



XT25Q08D

Quad IO Serial NOR Flash Datasheet

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Serial NOR Flash Memory

1.8V Multi I/O with 4KB, 32KB & 64KB Sector/Block Erase

8M -bit Serial Flash

- 1024K-bytes
- 256 bytes per programmable page
- Standard, Dual, Quad SPI, DTR
 - Standard SPI: SCLK, CS#, SI, SO, WP#, HOLD#/RESET#
 - Dual SPI: SCLK, CS#, IOO, IO1, WP#, HOLD#/RESET#
 - Quad SPI: SCLK, CS#, IO0, IO1, IO2, IO3
 - QPI: SCLK, CS#, IO0, IO1, IO2, IO3
 - SPI/QPI DTR(Double Transfer Rate) Read
- Flexible Architecture
 - Sector of 4K-bytes
 - Block of 32/64k-bytes
- Advanced security Features
 - 2*1024-Bytes Security Registers With OTP Lock
- Support 128 bits Unique ID
- Software/Hardware Write Protection
 - Write protect all/portion of memory via software
 - Enable/Disable protection with WP# Pin
 - Top or Bottom, Sector or Block selection

Package Options

- See 1.1 Available Ordering OPN
- All Pb-free packages are compliant RoHS, Halogen-Free and REACH.

- Temperature Range & Moisture Sensitivity Level
 - Industrial Level Temperature. (-40°C to +85°C), MSL3
- Power Consumption
 - 0.3uA typical Deep Power-Down current
- Single Power Supply Voltage
 - 1.65~2.0V
- Endurance and Data Retention
 - Minimum 100,000 Program/Erase Cycle
 - 20-year Data Retention typical
- High Speed Clock Frequency
 - 108MHz for fast read with 30pF load
 - Dual I/O Data transfer up to 216Mbit/s
 - Quad I/O Data transfer up to 432Mbit/s
 - QPI Mode Data transfer up to 432Mbit/s
 - DTR Quad I/O Data transfer up to 688Mbit/s

Program/Erase Speed

- Page Program time: 0.35ms typical
- Sector Erase time: 40ms typical
- Block Erase time: 0.12/0.15s typical
- Chip Erase time: 2.5s typical



CONTENTS

| 1. | GENERAL DESCRIPTION | . 5 |
|------|--|-----|
| 1.1. | Available Ordering OPN | . 5 |
| 1.2. | Connection Diagram | . 5 |
| 1.3. | Pin Description | . 6 |
| 1.4. | Block Diagram | . 6 |
| 1.5. | Memory Description | . 7 |
| 2. | DEVICE OPERATION | . 8 |
| 2.1. | SPI Mode | . 8 |
| 2.2. | QPI Mode | . 8 |
| 2.3. | DTR Read | . 8 |
| 2.4. | Hold Function | . 8 |
| 2.5. | RESET Function | . 9 |
| | The Reset Signaling Protocol (JEDEC 252) | |
| 3. | STATUS REGISTER | 11 |
| _ | | |
| 4. | DATA PROTECTION | 14 |
| 5. | COMMANDS DESCRIPTION | 16 |
| 5.1. | Basic Setting | 20 |
| 5.2. | Memory Read | 24 |
| 5.3. | Read Under DTR | 33 |
| 5.4. | Memory Program | 37 |
| 5.5. | Memory Erase | 40 |
| 5.6. | Security Register | 44 |
| 5.7. | Status Register | 46 |
| 5.8. | Deep Power-Down | 48 |
| 5.9. | Software Reset | 51 |
| 5.10 |). Read ID | 52 |
| 5.11 | . Advanced Data Protection | 64 |
| 5.12 | Suspend | 68 |
| 5.13 | . Wrap | 70 |
| 6. | ELECTRICAL CHARACTERISTICS | 72 |
| 6.1. | Power-Down & Power-on Timing | 72 |
| 6.2. | Initial Delivery State | 72 |
| 6.3. | Latch up Characteristics | 72 |
| 6.4. | Absolute Maximum Ratings | 73 |
| 6.5. | Capacitance Measurement Condition | 73 |
| 6.6. | DC Characteristics | 74 |
| 6.7. | AC Characteristics | 75 |
| 0.7. | | /5 |



| 7. | ORDERING INFORMATION | 78 |
|------|---------------------------|----|
| 8. | PACKAGE INFORMATION | 79 |
| 8.1. | Package SOP8 150MIL | 79 |
| 8.2. | Package DFN8 (2x3x0.4) mm | 80 |
| 9. | REVISION HISTORY | 81 |



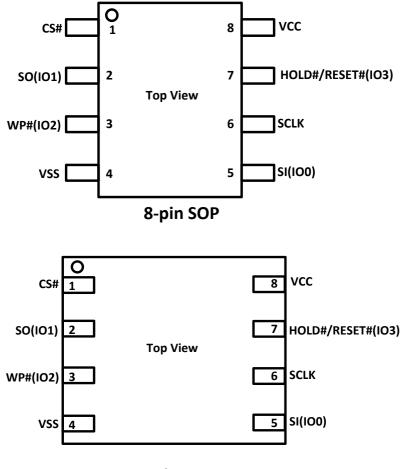
1. GENERAL DESCRIPTION

The XT25Q08D (8M-bit) Serial flash supports standard Serial Peripheral Interface (SPI), Dual/Quad SPI: Serial Clock, Chip Select, Serial Data I/O0 (SI), I/O1 (SO), I/O2 (WP#), and I/O3 (HOLD#/RESET#). The Dual I/O data is transferred with speed up to 216Mbit/s and the Quad I/O & Quad output data is transferred with speed up to 432Mbit/s.

1.1. Available Ordering OPN

| OPN | Package Type | Package Carrier |
|---------------|-----------------|-----------------|
| XT25Q08DSOIGU | SOP8 150mil | Tube |
| XT25Q08DSOIGT | SOP8 150mil | Tape & Reel |
| XT25Q08DDTIGT | DFN8 2x3x0.4 mm | Tape & Reel |

1.2. Connection Diagram



8-pin DFN



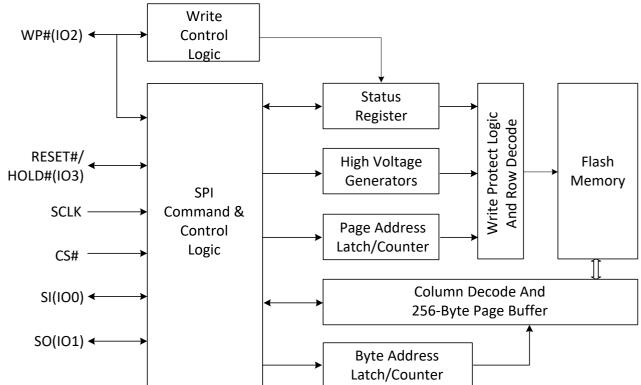
1.3. Pin Description

| Pin Name | I/O | Description |
|--------------------|-----|---|
| CS# | I | Chip Select Input |
| SO (IO1) | I/O | Data Output (Data Input Output 1) |
| WP# (IO2) | I/O | Write Protect Input (Data Input Output 2) |
| VSS | | Ground |
| SI (IO0) | I/O | Data Input (Data Input Output 0) |
| SCLK | I | Serial Clock Input |
| HOLD#/RESET# (IO3) | I/O | Hold or Reset Input (Data Input Output 3) |
| VCC | | Power Supply |

Notes:

1. IO0 and IO1 are used for Standard and Dual SPI instructions

2. IO0 – IO3 are used for Quad SPI instructions, WP# & HOLD# (or Reset#) functions are only available for Standard/Dual SPI.



1.4. Block Diagram



1.5. Memory Description

XT25Q08D

| Each Device has | Each block has | Each sector has | Each page has | |
|-----------------|----------------|-----------------|---------------|---------|
| 1024K | 64K/32K | 4К | 256 | bytes |
| 4К | 256/128 | 16 | - | pages |
| 256 | 16/8 | - | - | sectors |
| 16 | - | - | - | blocks |

Uniform Block Sector Architecture

| Block(64K-byte) | Block(32K-byte) | Sector(4K-byte) | Address Range | | |
|-----------------|-----------------|-----------------|---------------|---------|--|
| | | 255 | 0FF000H | OFFFFFH | |
| | 31 | | | | |
| 15 | | 248 | 0F8000H | 0F8FFFH | |
| 15 | | 247 | 0F7000H | 0F7FFFH | |
| | 30 | | | | |
| | | 240 | 0F0000H | OFOFFFH | |
| | | 239 | 0EF000H | OEFFFFH | |
| | 29 | | | | |
| 14 | | 232 | 0E8000H | 0E8FFFH | |
| 14 | | 231 | 0E7000H | 0E7FFFH | |
| | 28 | | | | |
| | | 224 | 0E0000H | OEOFFFH | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | 31 | 01F000H | 01FFFFH | |
| | 3 | | | | |
| 1 | | 24 | 018000H | 018FFFH | |
| T | | 23 | 017000H | 017FFFH | |
| | 2 | | | | |
| | | 16 | 010000H | 010FFFH | |
| | | 15 | 00F000H | 00FFFFH | |
| | 1 | | | | |
| 0 | | 8 | 008000H | 008FFFH | |
| 0 | | 7 | 007000H | 007FFFH | |
| | 0 | | | | |
| | | 0 | 000000H | 000FFFH | |



2. DEVICE OPERATION

2.1. SPI Mode

Standard SPI

The device features a serial peripheral interface on 4 signals bus: Serial Clock (SCLK), Chip Select (CS#), Serial Data Input (SI) and Serial Data Output (SO). Both SPI bus mode 0 and 3 are supported. Input data is latched on the rising edge of SCLK and data shifts out on the falling edge of SCLK.

Dual SPI

The device supports Dual SPI operation when using the "Dual Output Fast Read" and "Dual I/O Fast Read" (3BH and BBH) commands. These commands allow data to be transferred to or from the device at two times the rate of the standard SPI. When using the Dual SPI command the SI and SO pins become bidirectional I/O pins: IOO and IO1.

Quad SPI

The device supports Quad SPI operation when using the "Quad Output Fast Read", "Quad I/O Fast Read", "Quad I/O Word Fast Read" (6BH, EBH, E7H) commands. These commands allow data to be transferred to or from the device at four times the rate of the standard SPI. When using the Quad SPI command the SI and SO pins become bidirectional I/O pins: IOO and IO1, and WP# and HOLD# pins become IO2 and IO3. Quad SPI commands require the non-volatile Quad Enable bit (QE) in Status Register to be set.

2.2. QPI Mode

The device supports Quad Peripheral Interface (QPI) operations only when the device is switched from Standard/Dual/Quad SPI mode to QPI mode using the "Enable the QPI (38H)" command. The QPI mode utilizes all four IO pins to input the command code. Standard/Dual/Quad SPI mode and QPI mode are exclusive. Only one mode can be active at any given times. "Enable the QPI (38H)" and "Disable the QPI (FFH)" commands are used to switch between these two modes. Upon power-up and after software reset using "Enable Chip Reset (66H)" and "Reset (99H)" command, the default state of the device is Standard/Dual/Quad SPI mode. The QPI mode requires the non-volatile Quad Enable bit (QE) in Status Register to be set.

2.3. DTR Read

To effectively improve the read operation throughput without increasing the serial clock frequency, The device introduces multiple DTR (Double Transfer Rate) Read instructions that support Standard/Dual/Quad SPI and QPI modes. The byte-long instruction code is still latched into the device on the rising edge of the serial clock similar to all other SPI/QPI instructions. Once a DTR instruction code is accepted by the device, the address input and data output will be latched on both rising and falling edges of the SCLK.

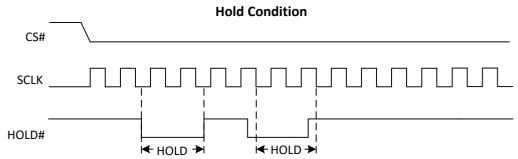
2.4. Hold Function

The HOLD# signal goes low to stop any serial communications with the device, but doesn't stop the operation of writing status register, programming, or erasing in progress.

The operation of HOLD needs CS# keeping low, and starts on the falling edge of the HOLD# signal, with SCLK signal being low (if SCLK is not being low, HOLD operation will not start until SCLK is being low). The HOLD condition ends on the rising edge of HOLD# signal with SCLK being low (If SCLK is not being low, HOLD operation will not end until SCLK is being low).

The SO is high impedance, and both SI and SCLK don't care during the HOLD operation, if CS# drives high during the HOLD operation, it will reset the internal logic of the device. To re-start the communication with the device, the HOLD# must be at high and then the CS# must be at low.



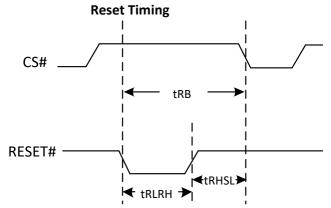


2.5. RESET Function

The RESET# pin allows the device to be reset by the control. The pin7 can be configured as a RESET# pin depending on the status register setting, which need QE=0 and HOLD/RST=1.

The RESET# pin goes low for a period of tRLRH or longer will reset the flash. After reset cycle, the flash is at the following states:

- Standby mode.
- All the volatile bits will return to the default status as power on.



| Symbol | Parameter | Min. | Тур. | Max. | Unit. |
|--------|-----------------------------|------|------|------|-------|
| tRLRH | Reset Pulse Width | 1 | | | us |
| tRHSL | Reset High Time Before Read | 200 | | | us |
| tRB | Reset Recovery Time | | | 1 | ms |



2.6. The Reset Signaling Protocol (JEDEC 252)

The protocol consists of two phases: reset request, and completion (a device internal reset).

Reset Request

- 1. CS# is driven active low to select the SPI slave (Note1)
- 2. Clock (SCLK) remains stable in either a high or low state (Note 2)
- 3. SI / IOO is driven low by the bus master, simultaneously with CS# going active low, (Note 3)
- 4. CS# is driven inactive (Note 4).

Repeat the steps 1-4 each time alternating the state of SI (Note 5).

NOTE 1 This powers up the SPI slave.

NOTE 2 This prevents any confusion with a command, as no command bits are transferred (clocked).

NOTE 3 No SPI bus slave drives SI during CS# low before a transition of SCLK, i.e., slave streaming output active is not allowed until after the first edge of SCK.

NOTE 4 The slave captures the state of SI on the rising edge of CS#.

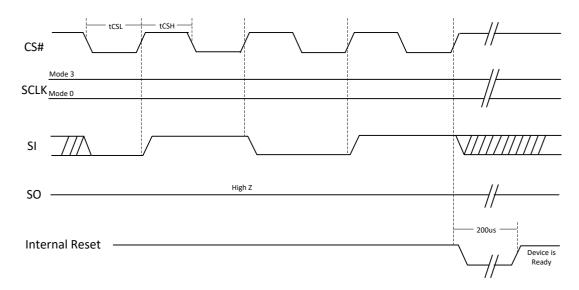
NOTE 5 SI is low on the first CS#, high on the second, low on the third, high on the fourth (This provides a 5h pattern, to differentiate it from random noise).

Reset Completion

After the fourth CS# pulse, the slave triggers its internal reset.

Timing Diagram and Timing Parameters

Figure 1. Reset Signaling Protocol



| Symbol | Parameter | Min. | Тур. | Max. | Unit. |
|--------|---------------|------|------|------|-------|
| tCSL | CS# Low Time | 500 | | | ns |
| tCSH | CS# High Time | 500 | | | ns |
| | Setup Time | 5 | | | ns |
| | Hold Time | 5 | | | ns |



WIP

3. STATUS REGISTER

BP4

BP3

| S23 | S22 | S21 | S20 | S19 | S18 | S17 | \$16 |
|----------|------|----------|----------|----------|------|-----------|----------|
| Hold/RST | DRV1 | DRV0 | Reserved | Reserved | WPS | LC | Reserved |
| | | | | | | | |
| S15 | S14 | S13 | S12 | S11 | S10 | S9 | S8 |
| SUS1 | СМР | Reserved | LB2 | LB1 | SUS2 | QE | SRP1 |
| | | | | | | | |
| S7 | S6 | S5 | S4 | S3 | S2 | S1 | SO |

BP2

HOLD/RST

SRPO

The HOLD/RST bit is used to determine whether HOLD# or RESET# function should be implemented on the hardware pin for 8-pin packages. When HOLD/RST=0, the pin acts as HOLD#, When the HOLD/RST=1, the pin acts as RESET#. However, the HOLD# or RESET# function are only available when QE=0, If QE=1, The HOLD# and RESET# functions are disabled, the pin acts as dedicated data I/O pin.

BP1

BP0

WEL

DRV1, DRV0

The Output Driver Strength (DRV1 & DRV0) bits are used to determine the output driver strength for the Read operations.

| DRV1 | DRVO | Driver Strength |
|------|------|-----------------|
| 0 | 0 | 25% |
| 0 | 1 | 50% |
| 1 | 0 | 75% (default) |
| 1 | 1 | 100% |

WPS

The WPS bit is used to select which Write Protect scheme should be used. When WPS=0, the device will use the combination of CMP, BP (4:0) bits to protect a specific area of the memory array. When WPS=1, the device will utilize the Individual Block Locks to protect any individual sector or blocks. The default value for all Individual Block Lock bits is 1 upon device power on or after reset.



LC

The Latency Code (LC) selects the mode and number of dummy cycles between the end of address and the start of read data output for command 0DH under QPI mode and command EDH under SPI/QPI modes.

Some read commands send mode bits following the address to indicate that the next command will be of the same type with an implied, rather than an explicit instruction. The next command thus does not provide an instruction Byte, only a new address and mode bits. This reduces the time needed to send each command when the same command type is repeated in a sequence of commands.

Dummy cycles provide additional latency that is needed to complete the initial read access of the flash array before data can be returned to the host system. Some read commands require additional latency cycles as the SCLK frequency is increased.

| LC | Dummy clock cycles |
|----|--------------------|
| 0 | 8 (Default) |
| 1 | 6 |

| Latency Code and DTR Mode Frequency Table |
|---|
|---|

SUS1, SUS2

The SUS1 and SUS2 bits are read only bits in the status register (S15 and S10) that are set to 1 after executing a Program/Erase Suspend (75H) command (The Erase Suspend will set the SUS1 to 1, and the Program Suspend will set the SUS2 to 1). The SUS1 and SUS2 bits are cleared to 0 by Program/Erase Resume (7AH) command, software reset (66H+99H) command as well as a power-down, power-up cycle.

СМР

The CMP bit is a non-volatile Read/Write bit in the Status Register (S14). It is used in conjunction the BP4-BP0 bits to provide more flexibility for the array protection. Please see the Status register Memory Protection table for details. The default setting is CMP=0.

LB1, LB2

The LB1, LB12 bits are non-volatile One Time Program (OTP) bits in Status Register (S11-S12) that provide the write protect control and status to the Security Registers. The default state of LB1-LB2 are 0, the security registers are unlocked. The LB1-LB2 bits can be set to 1 individually using the Write Register instruction. The LB1-LB2 bits are One Time Programmable, once its set to 1, the Security Registers will become read-only permanently.

QE

The Quad Enable (QE) bit is a non-volatile Read/Write bit in the Status Register that allows Quad operation. When the QE bit is set to 0 (Default) the WP# pin and HOLD# pin are enable. When the QE pin is set to 1, the Quad IO2 and IO3 pins are enabled. (The QE bit should never be set to 1 during standard SPI or Dual SPI operation if the WP# or HOLD# pins are tied directly to the power supply or ground).



SRP1, SRP0

The Status Register Protect (SRP1 and SRP0) bits are non-volatile Read/Write bits in the status register. The SRP bits control the type of write protection: software protection, hardware protection, power supply lock-down or one-time programmable protection.

| SRP1 | SRPO | WP# | Status Register | Description |
|------|------|-----|----------------------------|---|
| 0 | 0 | х | Software Protected | The Status Register can be written to after a Write Enable command, WEL=1. (Default) |
| 0 | 1 | 0 | Hardware Protected | WP#=0, the Status Register locked and cannot be written to. |
| 0 | 1 | 1 | Hardware Unprotected | WP#=1, the Status Register is unlocked and can be written to after a Write Enable command, WEL=1. |
| 1 | 0 | х | Power Supply Lock- Down | Status Register is protected and cannot be written to again until the next Power-Down, Power-Up cycle. Note 1 |
| 1 | 1 | х | One-Time Program Note 2 | Status Register is protected and cannot be written to. |

NOTE:

1. When SRP1, SRP0= (1, 0), a Power-Down, Power-Up cycle will change SRP1, SRP0 to (0, 0) state.

2. This feature is available on special order. Please contact XTX for details.

BP4, BP3, BP2, BP1, BP0

The Block Protect (BP4, BP3, BP2, BP1, BP0) bits are non-volatile. They define the size of the area to be software protected against Program and Erase commands. These bits are written with the Write Status Register (WRSR) command. When the Block Protect (BP4, BP3, BP2, BP1, BP0) bits are set to 1, the relevant memory area (as defined in Table 1.0 & 1.1) becomes protected against Page Program (PP), Sector Erase (SE) and Block Erase (BE) commands. The Block Protect(BP4, BP3, BP2, BP1, BP0) bits can be written provided that the Hardware Protected mode has not been set. The Chip Erase (CE) command is executed if the Block Protect (BP2, BP1, BP0) bits are 1 and CMP=1.

WEL

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write Status Register, Program or Erase command is accepted.

WIP

The Write In Progress (WIP) bit indicates whether the memory is busy in program/erase/write status register progress. When WIP bit sets to 1, means the device is busy in program/erase/write status register progress, when WIP bit sets 0, means the device is not in program/erase/write status register progress.



4. DATA PROTECTION

The device provide the following data protection methods:

■ Write Enable (WREN) command: The WREN command sets the Write Enable Latch bit (WEL). The WEL bit

will return to reset by the following situation:

- Power-Up / Software reset (66H+99H)
- Write Disable (WRDI)
- Write Status Register (WRSR)
- Page Program (PP)
- Sector Erase (SE) / Block Erase (BE) / Chip Erase (CE)
- Erase Security Register / Program Security Register
- Software Protection Mode: The Block Protect (BP4, BP3, BP2, BP1, BP0) bits, WPS bit and CMP bit define the section of the memory array that can be read but cannot be changed.
- Hardware Protection Mode: WP# goes low to prevent writing status register.
- Deep Power-Down Mode: In Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down Mode command (ABH) and software reset (66H+99H).

| Status Register Content | | | | | Memory Content | | | | | | |
|-------------------------|-----|-----|-----|-----|----------------|------------------|---------|--------------|--|--|--|
| BP4 | BP3 | BP2 | BP1 | BP0 | Blocks | Addresses | Density | Portion | | | |
| Х | Х | 0 | 0 | 0 | NONE | NONE | NONE | NONE | | | |
| 0 | 0 | 0 | 0 | 1 | 15 | 0F0000H-0FFFFFH | 64KB | Upper 1/16 | | | |
| 0 | 0 | 0 | 1 | 0 | 14 to 15 | 0E0000H-0FFFFFH | 128KB | Upper 1/8 | | | |
| 0 | 0 | 0 | 1 | 1 | 12 to 15 | 0C0000H-0FFFFH | 256KB | Upper 1/4 | | | |
| 0 | 0 | 1 | 0 | 0 | 8 to 15 | 080000H-0FFFFH | 512KB | Upper 1/2 | | | |
| 0 | 1 | 0 | 0 | 1 | 0 | 000000H-00FFFFH | 64KB | Lower 1/16 | | | |
| 0 | 1 | 0 | 1 | 0 | 0 to 1 | 1 000000H-01FFFH | | Lower 1/8 | | | |
| 0 | 1 | 0 | 1 | 1 | 0 to 3 | 000000H-03FFFFH | 256KB | Lower 1/4 | | | |
| 0 | 1 | 1 | 0 | 0 | 0 to 7 | 000000H-07FFFFH | 512KB | Lower 1/2 | | | |
| 0 | Х | 1 | 0 | 1 | 0 to 15 | 000000H-0FFFFH | 1MB | ALL | | | |
| Х | Х | 1 | 1 | Х | 0 to 15 | 000000H-0FFFFH | 1MB | ALL | | | |
| 1 | 0 | 0 | 0 | 1 | 15 | 0FF000H-0FFFFFH | 4KB | Top Block | | | |
| 1 | 0 | 0 | 1 | 0 | 15 | 0FE000H-0FFFFFH | 8KB | Top Block | | | |
| 1 | 0 | 0 | 1 | 1 | 15 | 0FC000H-0FFFFFH | 16KB | Top Block | | | |
| 1 | 0 | 1 | 0 | Х | 15 | 0F8000H-0FFFFFH | 32KB | Top Block | | | |
| 1 | 1 | 0 | 0 | 1 | 0 | 000000H-000FFFH | 4KB | Bottom Block | | | |
| 1 | 1 | 0 | 1 | 0 | 0 | 000000H-001FFFH | 8KB | Bottom Block | | | |
| 1 | 1 | 0 | 1 | 1 | 0 | 000000H-003FFFH | 16KB | Bottom Block | | | |
| 1 | 1 | 1 | 0 | Х | 0 | 000000H-007FFFH | 32KB | Bottom Block | | | |

Table1.0 XT25Q08D Protected area size (WPS=0, CMP=0)



Table1.1 XT25Q08D Protected area size (WPS=0, CMP=1)

| Status Register Content | | | | | Memory Content | | | | | | |
|-------------------------|-----|-----|-----|-----|----------------|-----------------|---------|---------------|--|--|--|
| BP4 | BP3 | BP2 | BP1 | BP0 | Blocks | Addresses | Density | Portion | | | |
| Х | Х | 0 | 0 | 0 | ALL | 000000H-0FFFFH | 1M | ALL | | | |
| 0 | 0 | 0 | 0 | 1 | 0 to 14 | 000000H-0EFFFH | 960KB | Lower 15/16 | | | |
| 0 | 0 | 0 | 1 | 0 | 0 to 13 | 000000H-0DFFFFH | 896KB | Lower 7/8 | | | |
| 0 | 0 | 0 | 1 | 1 | 0 to 11 | 000000H-0BFFFFH | 768KB | Lower 3/4 | | | |
| 0 | 0 | 1 | 0 | 0 | 0 to 7 | 000000H-07FFFFH | 512KB | Lower 1/2 | | | |
| 0 | 1 | 0 | 0 | 1 | 1 to 15 | 010000H-0FFFFFH | 960KB | Upper 15/16 | | | |
| 0 | 1 | 0 | 1 | 0 | 2 to 15 | 020000H-0FFFFFH | 896KB | Upper 7/8 | | | |
| 0 | 1 | 0 | 1 | 1 | 4 to 15 | 040000H-0FFFFFH | 768KB | Upper 3/4 | | | |
| 0 | 1 | 1 | 0 | 0 | 8 to 15 | 080000H-0FFFFFH | 512KB | Upper 1/2 | | | |
| 0 | Х | 1 | 0 | 1 | NONE | NONE | NONE | NONE | | | |
| Х | Х | 1 | 1 | Х | NONE | NONE | NONE | NONE | | | |
| 1 | 0 | 0 | 0 | 1 | 0 to 15 | 000000H-0FEFFFH | 1020KB | Lower 255/256 | | | |
| 1 | 0 | 0 | 1 | 0 | 0 to 15 | 000000H-0FDFFFH | 1016KB | Lower 127/128 | | | |
| 1 | 0 | 0 | 1 | 1 | 0 to 15 | 000000H-0FBFFFH | 1008KB | Lower 63/64 | | | |
| 1 | 0 | 1 | 0 | Х | 0 to 15 | 000000H-0F7FFFH | 992KB | Lower 31/32 | | | |
| 1 | 1 | 0 | 0 | 1 | 0 to 15 | 001000H-0FFFFFH | 1020KB | Upper 255/156 | | | |
| 1 | 1 | 0 | 1 | 0 | 0 to 15 | 002000H-0FFFFFH | 1016KB | Upper 127/128 | | | |
| 1 | 1 | 0 | 1 | 1 | 0 to 15 | 004000H-0FFFFFH | 1008KB | Upper 63/64 | | | |
| 1 | 1 | 1 | 0 | Х | 0 to 15 | 008000H-0FFFFH | 992KB | Upper 31/32 | | | |

Table1.2 XT25Q08D Individual Block Protection (WPS=1)

| Block | Sector | Addro | Individual Block Lock Operation | |
|-------|--------|---------|------------------------------------|------------------------------------|
| | 255 | 0FF000H | The Top/Bottom block | |
| 15 | | | | is protected by sector. |
| | 240 | 0F0000H | OFOFFFH | Other 14 Blocks are |
| | | | protected by block | |
| | | | | Block Lock: |
| | | | | 36H+Address |
| 2 | | | | Block Unlock: |
| | | | | 39H+Address |
| 1 | | | | Read Block Lock: 3DH+Address |
| | 15 | 00F000H | 00FFFFH | Global Block Lock: |
| 0 | | | | 7EH |
| | 0 | 000000H | 000FFFH | Global Block Unlock: 98H |



5. COMMANDS DESCRIPTION

All commands, addresses and data are shifted in and out of the device, beginning with the most significant bit on the first rising edge of SCLK after CS# is driven low. Then, the one-byte command code must be shifted in to the device, most significant bit first on SI, each bit being latched on the rising edges of SCLK.

See Table 2, every command sequence starts with a one-byte command code. Depending on the command, this might be followed by address bytes, or by data bytes, or by both or none. CS# must be driven high after the last bit of the command sequence has been shifted in. For the command of Read, Fast Read, Read Status Register or Release from Deep Power-Down, and Read Device ID, the shifted-in command sequence is followed by a data-out sequence. CS# can be driven high after any bit of the data-out sequence is being shifted out.

For the command of Page Program, Sector Erase, Block Erase, Chip Erase, Write Status Register, Write Enable or Write Disable command, CS# must be driven high exactly at the byte boundary, otherwise the command is rejected, and is not executed. That is CS# must be driven high when the number of clock pulses after CS# being driven low is an exact multiple of eight. For Page Program, if at any time the input byte is not a full byte, nothing will happen and WEL will not be reset.

| Command Name | SPI | QPI | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 | n-Bytes |
|--|-----|-----|-------|--------------------------------|-------------------------------|------------------------|------------------------|------------------------|--------------|
| Basic Setting | | | | | | | | | |
| Enable QPI | ٧ | | 38H | | | | | | |
| Write Enable | ٧ | ٧ | 06H | | | | | | |
| Write Enable For Volatile | V | ٧ | 50H | | | | | | |
| Write Disable | ٧ | ٧ | 04H | | | | | | |
| Continuous Read Reset / Disable QPI | ٧ | v | FFH | | | | | | |
| High Speed Mode | ٧ | ٧ | A3H | dummy | dummy | dummy | | | |
| Memory Read | | | | | | | | | |
| Normal Read | ٧ | | 03H | A23-A16 | A15-A8 | A7-A0 | (D7-D0) | (Next byte) | (continuous) |
| Fast Read | V | ٧ | ОВН | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) | (continuous) |
| Dual Output Fast Read | ٧ | | 3BH | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) ⁽¹⁾ | (continuous) |
| Dual I/O Fast Read | ٧ | | BBH | A23-A8 ⁽²⁾ | A7-A0 M7-M0 ⁽²⁾ | (D7-D0) ⁽¹⁾ | | | (continuous) |
| Quad Output Fast Read | ٧ | | 6BH | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) ⁽³⁾ | (continuous) |
| Quad I/O Fast Read | ٧ | ٧ | EBH | A23-A0 M7-M0 ⁽⁴⁾ | dummy ⁽⁵⁾ | (D7-D0) ⁽³⁾ | | | (continuous) |
| Quad I/O Word Fast Read | ٧ | | E7H | A23-A0 M7-M0 ⁽⁴⁾ | dummy ⁽⁶⁾ | (D7-D0) ⁽³⁾ | | | (continuous) |
| Read Under DTR | | | | | | | | | |
| DTR Fast Read | ٧ | V | 0DH | A23-A16 | A15-A8 | A7-A0 | Dummy | (D7-D0) | |
| DTR Fast Read Dual I/O | V | | BDH | A23-A16 | A15-A8 | A7-A0 | M7-M0 | Dummy | (D7-D0) |
| DTR Fast Read Quad I/O | V | ٧ | EDH | A23-A16 | A15-A8 | A7-A0 | M7-M0 | Dummy | (D7-D0) |
| Memory Program | | | | | | | | | |
| Page Program | V | ٧ | 02H | A23-A16 | A15-A8 | A7-A0 | (D7-D0) | (Next byte) | |
| Quad Page Program | V | | 32H | A23-A16 | A15-A8 | A7-A0 | (D7-D0) ⁽³⁾ | | |
| Memory Erase | | | | | | | | | |
| Sector Erase | ٧ | V | 20H | A23-A16 | A15-A8 | A7-A0 | | | |

Table 2. Commands

1.8V Quad IO Serial Flash

XT25Q08D

| | | | | 1.07 Que | | 1511 | | , | |
|--|--------|--------|--------------------|-------------------|------------------|--------------------|---------|-------------|--------------|
| 32kB Block Erase | V | v | 52H | A23-A16 | A15-A8 | A7-A0 | | | |
| 64kB Block Erase | V | V | D8H | A23-A16 | A15-A8 | A7-A0 | | | |
| Chip Erase | V | V | 60H/C7H | | | | | | |
| Security Register | | | | | | | | | |
| Read Security Register ⁽⁸⁾ | V | | 48H | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) | |
| Program Security Register ⁽⁸⁾ | V | | 42H | A23-A16 | A15-A8 | A7-A0 | (D7-D0) | (Next byte) | |
| Erase Security Register ⁽⁸⁾ | V | | 44H | A23-A16 | A15-A8 | A7-A0 | | | |
| Status Register | | | | | | | | | |
| Read Status Register 1 | V | V | 05H | (S7-S0) | | | | | (continuous) |
| Read Status Register 2 | V | V | 35H | (S15-S8) | | | | | (continuous) |
| Read Status Register 3 | V | V | 15H | (S23-S16) | | | | | (continuous) |
| Write Status Register 1 | V | V | 01H | (S7-S0) | | | | | (continuous) |
| Write Status Register 2 | V | V | 31H | (S15-S8) | | | | | (continuous) |
| Write Status Register 3 | V | V | 11H | (S23-S16) | | | | | (continuous) |
| Deep Power-Down | • | | | | | | | | |
| Deep Power-Down | V | V | B9H | | | | | | |
| Release From Deep Power- Down | v | ٧ | ABH | | | | | | |
| Release From Deep Power- Down, And Read Device ID | V | ٧ | ABH | | | | | | |
| Software Reset | | | | | | | | | |
| Enabale Reset | V | V | 66H | | | | | | |
| Reset | V | ٧ | 99H | | | | | | |
| Read ID | | | | | | | | | |
| Read Manufacture ID | V | ٧ | 90H | dummy | dummy | 00H | (M7-M0) | (D7-D0) | (continuous) |
| Read Manufacture ID Dual I/O | V | | 92H | A23-A8 | A7-A0, M[7:0] | (M7-M0) (D7-D0) | | | (continuous) |
| Read Manufacture ID Quad I/O | v | | 94H | A23-A0, M[7:0] | dummy | (M7-M0) (D7-D0) | | | |
| Read JEDEC ID | V | V | 9FH | (M7-M0) | (D15-D8) | (D7-D0) | | | (continuous) |
| Read Unique ID | V | V | 4BH | dummy | dummy | dummy | dummy | (D7-D0) | (continuous) |
| Read SFDP | V | V | 5AH | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) | (continuous) |
| Advanced Data Protection | | 1 | 11 | | 11 | | 1 | I | I |
| Single Block Lock | V | V | 36H | A23-A16 | A15-A8 | A7-A0 | | | |
| Single Block Unlock | V | ٧ | 39H | A23-A16 | A15-A8 | A7-A0 | | | |
| Read Block Lock | V | ٧ | 3DH | A23-A16 | A15-A8 | A7-A0 | | | |
| Global Block Lock | V | ٧ | 7EH | | | | | | |
| Global Block Unlock | V | ٧ | 98H | | | | | | |
| Suspend | 1 | 1 | <u> </u> | | ı | | 1 | | |
| Drogram Frace Succord | | | | | | | | | |
| Program Erase Suspend | V | V | 75H/B0H | | | | | | |
| Program Erase Resume | v v | v v | 75H/B0H 7AH/30H | | | | | | |



XT25Q08D

| Set Burst With Wrap | ٧ | | 77H | dummy | dummy | dummy | W6-W4 | | |
|----------------------|---|---|-----|---------|--------|-------|-------|---------|--|
| Set Read Parameters | | ٧ | СОН | P7-P0 | | | | | |
| Burst Read With Wrap | | ٧ | 0CH | A23-A16 | A15-A8 | A7-A0 | dummy | (D7-D0) | |

NOTE:

1. Dual Output data

IO0 = (D6, D4, D2, D0) IO1 = (D7, D5, D3, D1)

2. Dual Input Address

IO0 = A22, A20, A18, A16, A14, A12, A10, A8, A6, A4, A2, A0, M6, M4, M2, M0 IO1 = A23, A21, A19, A17, A15, A13, A11, A9, A7, A5, A3, A1, M7, M5, M3, M1

3. Quad Output Data

IO0 = (D4, D0,) IO1 = (D5, D1,) IO2 = (D6, D2,) IO3 = (D7, D3,)

4. Quad Input Address

- IO0 = A20, A16, A12, A8, A4, A0, M4, M0 IO1 = A21, A17, A13, A9, A5, A1, M5, M1 IO2 = A22, A18, A14, A10, A6, A2, M6, M2 IO3 = A23, A19, A15, A11, A7, A3, M7, M3
- 5. Quad I/O Fast Read Data

IO0 = (x, x, x, x, D4, D0,...) IO1 = (x, x, x, x, D5, D1,...) IO2 = (x, x, x, x, D6, D2,...) IO3 = (x, x, x, x, D7, D3,...)

6. Quad I/O Word Fast Read Data

IO0 = (x, x, D4, D0,...) IO1 = (x, x, D5, D1,...) IO2 = (x, x, D6, D2,...) IO3 = (x, x, D7, D3,...)

7. Quad I/O Word Fast Read Data: the lowest address bit must be 0.

8. Security Registers Address:

Security Register1: A23-A16=00H, A15-A8=10H, A7-A0= Byte Address; Security Register2: A23-A16=00H, A15-A8=20H, A7-A0= Byte Address;

9. QPI Command, Address, Data input/output format:

CLK# = 0 1 2 3 4 5 6 7 8 9 10 11 IO0 = C4, C0, A20, A16, A12, A8, A4, A0, D4, D0, D4, D0 IO1 = C5, C1, A21, A17, A13, A9, A5, A1, D5, D1, D5, D1 IO2 = C6, C2, A22, A18, A14, A10, A6, A2, D6, D2, D6, D2 IO3 = C7, C3, A23, A19, A15, A11, A7, A3, D7, D3, D7, D4

- 10. QPI mode: Release from Deep Power-Down, And Read Device ID (ABH) N dummy cycles should be inserted before ID read cycle, refer to COH command
- 11. QPI mode: Manufacturer/Device ID (90H) N dummy cycles should be inserted before ID read cycle, refer to COH command



Table of Device ID Definitions:

XT25Q08D

| Operation Code | MID7-MID0 | ID15-ID8 | ID7-ID0 |
|-----------------------|-----------|----------|---------|
| 9FH | OB | 60 | 14 |
| 90H | ОВ | | 13 |
| АВН | | | 13 |



5.1. Basic Setting

5.1.1. Enable QPI (38H)

The device support both Standard/Dual/Quad SPI and QPI mode. The "Enable QPI (38H)" command can switch the device from SPI mode to QPI mode. See the command Table 2a for all support QPI commands. In order to switch the device to QPI mode, the Quad Enable (QE) bit in Status Register-1 must be set to 1 first, and "Enable QPI (38H)" command must be issued. If the QE bit is 0, the "Enable QPI (38H)" command will be ignored and the device will remain in SPI mode. When the device is switched from SPI mode to QPI mode, the existing Write Enable Latch and the Wrap Length setting will remain unchanged.

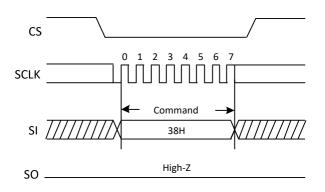
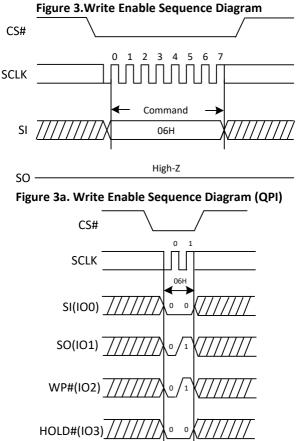


Figure 2. Enable QPI mode command Sequence Diagram

5.1.2. Write Enable (06H)

The Write Enable (WREN) command is for setting the Write Enable Latch (WEL) bit. The Write Enable Latch (WEL) bit must be set prior to every Page Program (PP), Sector Erase (SE), Block Erase (BE), Chip Erase (CE), Program Security Register, Erase Security Register and Write Status Register (WRSR) command. The Write Enable (WREN) command sequence: CS# goes low \rightarrow Sending the Write Enable command \rightarrow CS# goes high.

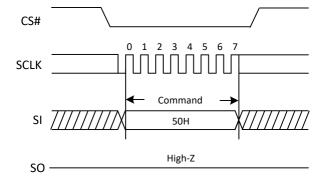




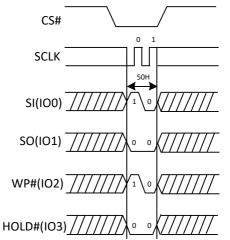
5.1.3. Write Enable for Volatile Status Register (50H)

The non-volatile Status Register bits can also be written to as volatile bits. This gives more flexibility to change the system configuration and memory protection schemes quickly without waiting for the typical non-volatile bit write cycles or affecting the endurance of the Status Register non-volatile bits. The Write Enable for Volatile Status Register command must be issued prior to a Write Status Register command and any other commands can't be inserted between them. Otherwise, Write Enable for Volatile Status Register will be cleared. The Write Enable for Volatile Status Register command to change the volatile Status Register bit values.





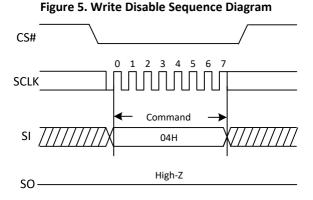




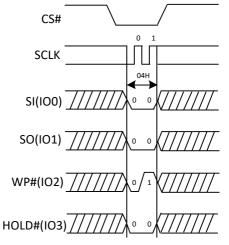


5.1.4. Write Disable (04H)

The Write Disable command is for resetting the Write Enable Latch (WEL) bit. The Write Disable command sequence: CS# goes low \rightarrow Sending the Write Disable command \rightarrow CS# goes high. The WEL bit is reset by following condition: Power-up and upon completion of the Write Status Register, Page Program, Sector Erase, Block Erase and Chip Erase commands.



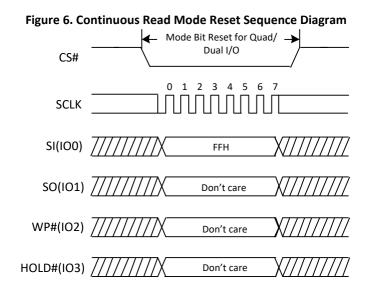






5.1.5. Continuous Read Mode Reset / Disable QPI (FFH)

The Dual/Quad I/O Fast Read operations, "Continuous Read Mode" bits (M7-0) are implemented to further reduce command overhead. By setting the (M7-0) to "AXH", the next Dual/Quad I/O Fast Read operations do not require the BBH/EBH/E7H/BDH/EDH command code. If Continuous Read Mode bits are set to "AXH", the device will not recognize any standard SPI commands. So Continuous Read Mode Reset command will release the Continuous Read Mode from the "AXH" state and allow standard SPI command to be recognized.



Disable QPI (FFH)

To exit the QPI mode and return to Standard/Dual/Quad SPI mode, the "Disable QPI (FFH)" command must be issued. When the device is switched from QPI mode to SPI mode, the existing Write Enable Latch and the Wrap Length setting will remain unchanged. When the device is in QPI mode, the first FFH command will exit continuous read mode and the second FFH command will exit QPI mode.

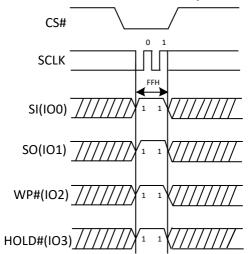


Figure 6a. Disable QPI mode command Sequence Diagram

5.1.6. High Speed Mode (A3H)

The High Speed Mode (HSM) command must be executed prior to Dual or Quad I/O commands when operating at high frequencies and continuous read mode (see AC Electrical Characteristics). This command allows pre-charging of internal charge pumps so the voltages required for accessing the flash memory array are readily available. The command sequence: CS# goes low \rightarrow Sending A3H command \rightarrow Sending 3-dummy byte \rightarrow CS# goes high. After the HSM command is executed, the device will maintain a slightly higher standby current than standard SPI operation. The Write Enable command (06H) can be used to return to standard SPI standby current.



In addition, Deep Power-Down command (B9H) will release the device from HSM mode to deep power down state.



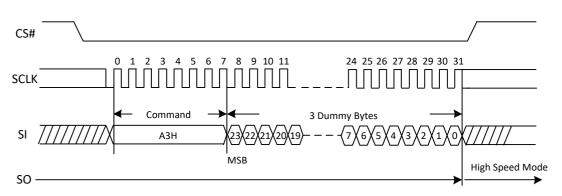
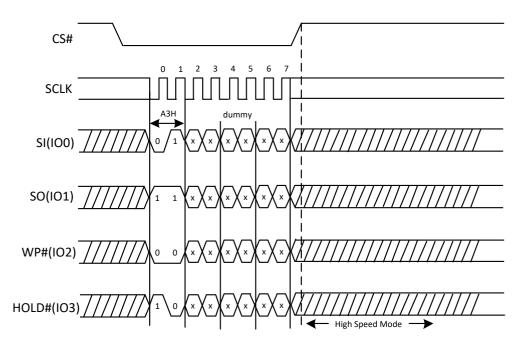


Figure 7a. High Speed Mode Sequence Diagram (QPI)

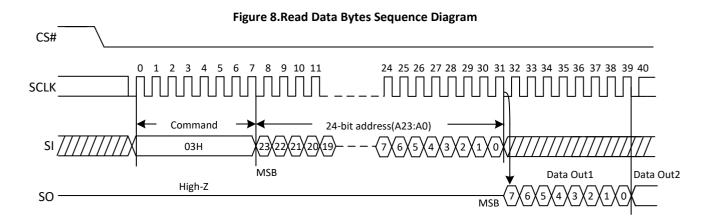


5.2. Memory Read

5.2.1. Normal Read (03H)

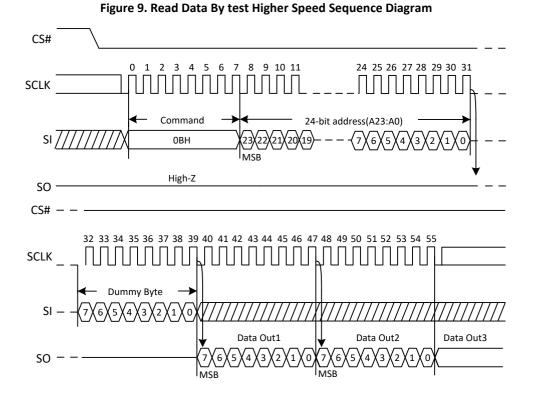
The Read Data Bytes (READ) command is followed by a 3-byte address (A23-A0), each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fR, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. The whole memory can, therefore, be read with a single Read Data Bytes (READ) command. Any Read Data Bytes (READ) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.





5.2.2. Fast Read (0BH)

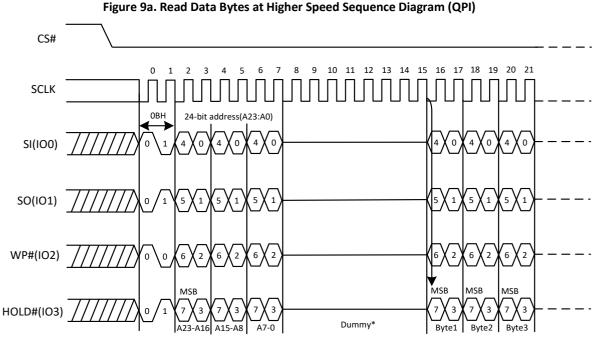
The Read Data Bytes at Higher Speed (Fast Read) command is for quickly reading data out. It is followed by a 3-byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fC, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.



Fast Read (OBH) in QPI mode

The Fast Read command is also supported in QPI mode. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8.

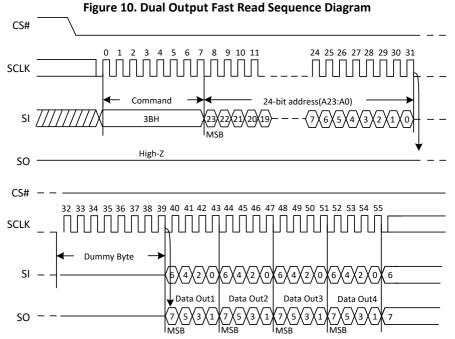




*Set Read Parameters Command (COH) can set the number of dummy clocks

5.2.3. Dual Output Fast Read (3BH)

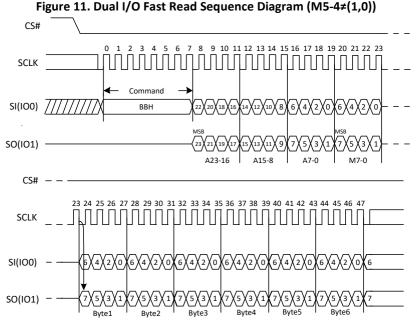
The Dual Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in the following figure. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.





5.2.4. Dual I/O Fast Read (BBH)

The Dual I/O Fast Read command is similar to the Dual Output Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte 2-bit per clock by SI and SO, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in the following figure. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.



Dual I/O Fast Read with "Continuous Read Mode"

The Dual I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5-4) =(1, 0), then the next Dual I/O Fast Read command (after CS# is raised and then lowered) does not require the BBH command code. The command sequence is shown in Figure10a. If the "Continuous Read Mode" bits (M5-4) do not equal (1, 0), the next command requires the first BBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5-4) before issuing normal command.

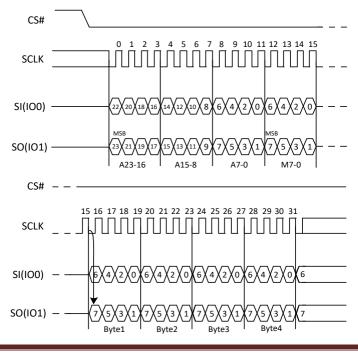
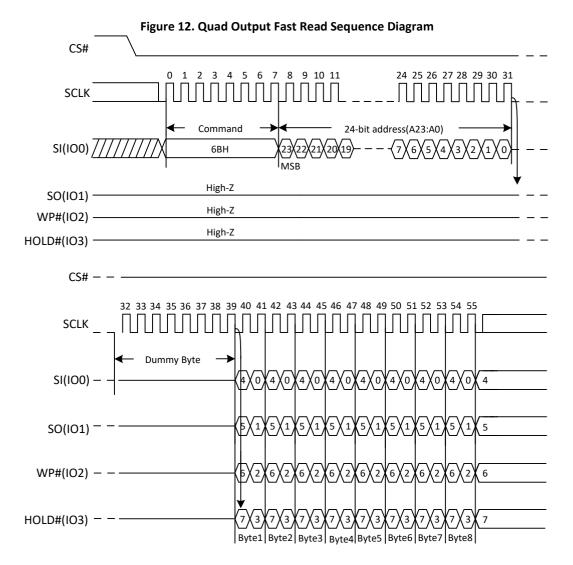


Figure 11a. Dual I/O Fast Read Sequence Diagram (M5-4=(1,0))



5.2.5. Quad Output Fast Read (6BH)

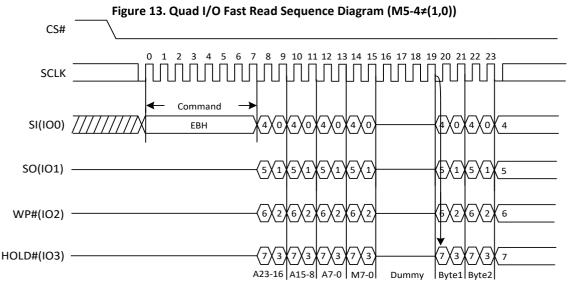
The Quad Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO3, IO2, IO1 and IO0. The command sequence is shown in Figure 11. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.





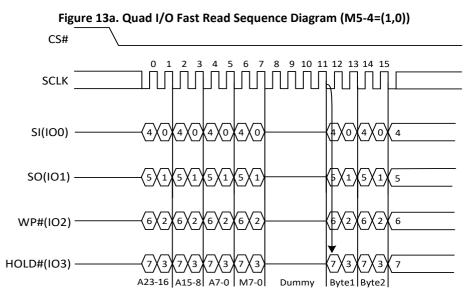
5.2.6. Quad I/O Fast Read (EBH)

The Quad I/O Fast Read command is similar to the Dual I/O Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte and 4 dummy clock 4-bit per clock by IOO, IO1, IO3, IO4, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IOO, IO1, IO2, IO3. The command sequence is shown in the figure below. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Fast read command.



Quad I/O Fast Read with "Continuous Read Mode"

The Quad I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5-4) =(1, 0), then the next Quad I/O Fast Read command (after CS# is raised and then lowered) does not require the EBH command code. The command sequence is shown in Figure12a. If the "Continuous Read Mode" (M5-4) do not equal (1, 0), the next command requires the first EBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5-4) before issuing normal command.





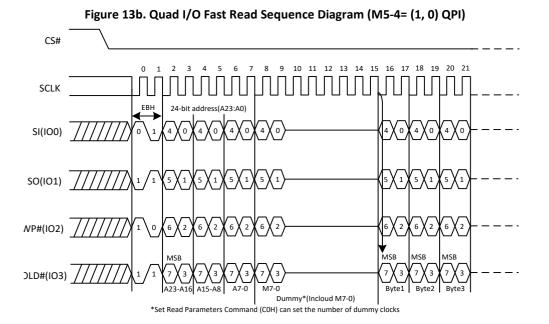
Quad I/O Fast Read with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

The Quad I/O Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to EBH. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following EBH commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands.

Quad I/O Fast Read (EBH) in QPI mode

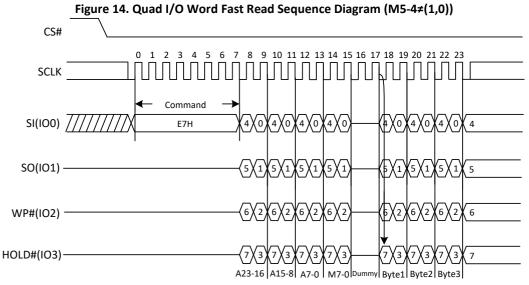
The Quad I/O Fast Read command is also supported in QPI mode. See the figure below. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8. In QPI mode, the "Continuous Read Mode" bits M7-M0 are also considered as dummy clocks. "Continuous Read Mode" feature is also available in QPI mode for Quad I/O Fast Read command. "Wrap Around" feature is not available in QPI mode for Quad I/O Fast Read command. To perform a read operation with fixed data length wrap around in QPI mode, a dedicated "Burst Read with Wrap" (OCH) command must be used.





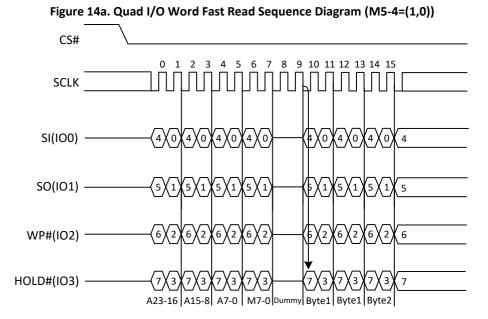
5.2.7. Quad I/O Word Fast Read (E7H)

The Quad I/O Word Fast Read command is similar to the Quad I/O Fast Read command except that the lowest address bit (A0) must equal 0 and only 2 dummy clock. The command sequence is shown in followed Figure13. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Word Fast read command.



Quad I/O Word Fast Read with "Continuous Read Mode"

The Quad I/O Word Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5- 4) = (1, 0), then the next Quad I/O Word Fast Read command (after CS# is raised and then lowered) does not require the E7H command code. The command sequence is shown in Figure13a. If the "Continuous Read Mode" bits (M5- 4) do not equal (1, 0), the next command requires the first E7H command code, thus returning to normal operation. A "Continuous Read Mode Reset" command can be used to reset (M7-0) before issuing normal command.





Quad I/O Word Fast Read with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

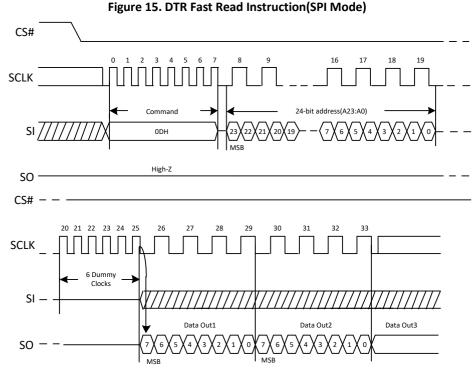
The Quad I/O Word Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to E7H. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following E7H commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command. The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands.



5.3. Read Under DTR

5.3.1. Single Read Under DTR (0DH)

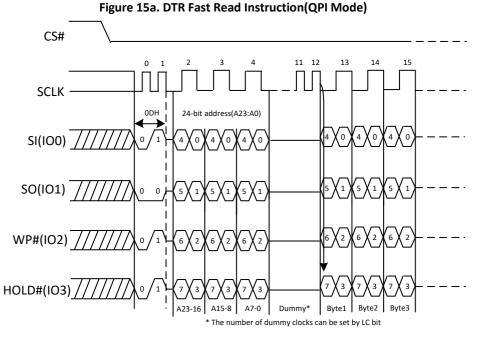
The DTR Fast Read instruction is similar to the Fast Read instruction except that the 24-bit address input and the data output require DTR (Double Transfer Rate) operation. This is accomplished by adding six dummy clocks after the 24-bit address as shown in Figure 14. The dummy clocks allow the devices internal circuits additional time for setting up the initial address. During the dummy clocks the data value on the SO pin is a "don't care".



DTR Fast Read (0DH) in QPI Mode

The DTR Fast Read instruction is also supported in QPI mode.

The number of dummy clocks for "DTR Fast Read" (0DH) under QPI mode and "DTR Fast Read Quad I/O" (EDH) can be set by the Latency Code (LC) in status register. When the LC bit is set to 0, which is default, the number of dummy clock cycles is 8. When the LC bit is set to 1, the dummy clock cycles is 6.

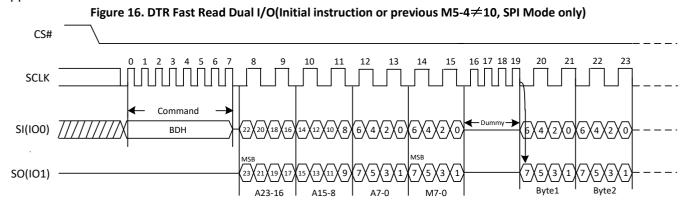




5.3.2. DTR Fast Read Dual I/O (BDH)

The DTR Fast Read Dual I/O (BDH) instruction allows for improved random access while maintaining two IO pins, IOO and IO1. It is similar to the Fast Read Dual Output (3BH) instruction but with the capability to input the Address bits (A23-0) two bits per clock. Six dummy clocks(including M7-0) will follow the 24-bit address. The dummy clocks allow the devices internal circuits additional time for setting up the initial address. During the dummy clocks the data value on the SO pin is a "don't care".

This reduced instruction overhead may allow for code execution (XIP) directly from the Dual SPI in some applications.



DTR Fast Read Dual I/O with "Continuous Read Mode"

The DTR Fast Read Dual I/O instruction can further reduce instruction overhead through setting the "Continuous Read Mode" bits (M7-0) after the input Address bits (A23-0), as shown in Figure 15a. The upper nibble of the (M7-4) controls the length of the next Fast Read Dual I/O instruction through the inclusion or exclusion of the first byte instruction code. The lower nibble bits of the (M3-0) are don't care ("x"). However, the IO pins should be high-impedance prior to the falling edge of the first data out clock.

If the "Continuous Read Mode" bits M5-4 = (1,0), then the next DTR Fast Read Dual I/O instruction (after CS# is raised and then lowered) does not require the BDH instruction code, as shown in Figure 15a. This reduces the instruction sequence by eight clocks and allows the Read address to be immediately entered after CS# is asserted low. If the "Continuous Read Mode" bits M5-4 do not equal to (1,0), the next instruction (after CS# is raised and then lowered) requires the first byte instruction code, thus returning to normal operation. It is recommended to input FFFFh/FFFFh on IOO (lasting 16 or 20 clocks) for the next instruction to ensure M4 = 1 and return the device to normal operation.

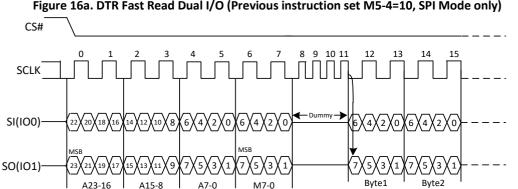


Figure 16a. DTR Fast Read Dual I/O (Previous instruction set M5-4=10, SPI Mode only)

5.3.3. DTR Fast Read Quad I/O (EDH)

The DTR Fast Read Quad I/O (EDH) instruction is similar to the Quad I/O Fast Read (EBH) instruction except that address and data bits are input and output through four pins IO0, IO1, IO2 and IO3 and several Dummy clocks(including M7-M0) are required in SPI mode prior to the data output. The Quad I/O dramatically reduces instruction overhead allowing faster random access for code execution (XIP) directly from the Quad SPI. The



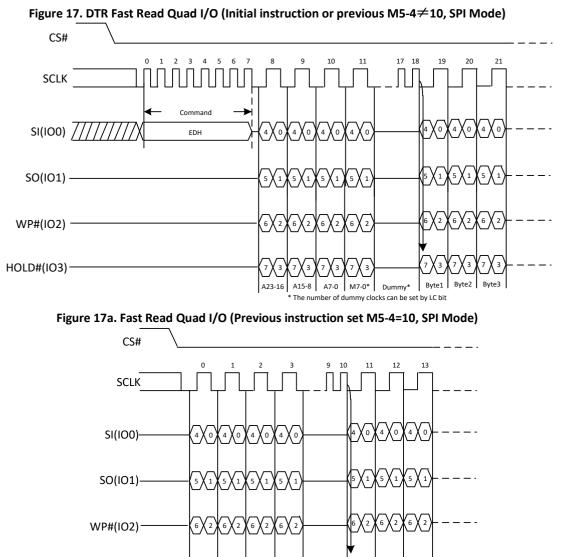
Quad Enable bit (QE) of Status Register-2 must be set to enable the DTR Fast Read Quad I/O Instruction.

The number of dummy clocks for "DTR Fast Read" (0DH) under QPI mode and "DTR Fast Read Quad I/O" (EDH) can be set by the Latency Code (LC) in status register. When the LC bit is set to 0, which is default, the number of dummy clock cycles is 8. When the LC bit is set to 1, the dummy clock cycles is 6.

DTR Fast Read Quad I/O with "Continuous Read Mode"

The DTR Fast Read Quad I/O instruction can further reduce instruction overhead through setting the "Continuous Read Mode" bits (M7-0) after the input Address bits (A23-0), as shown in Figure 16a. The upper nibble of the (M7-4) controls the length of the next Fast Read Quad I/O instruction through the inclusion or exclusion of the first byte instruction code. The lower nibble bits of the (M3-0) are don't care ("x"). However, the IO pins should be high-impedance prior to the falling edge of the first data out clock.

If the "Continuous Read Mode" bits M5-4 = (1,0), then the next DTR Fast Read Quad I/O instruction (after CS# is raised and then lowered) does not require the EDH instruction code. This reduces the instruction sequence by eight clocks and allows the Read address to be immediately entered after CS# is asserted low. If the "Continuous Read Mode" bits M5-4 do not equal to (1,0), the next instruction (after CS# is raised and then lowered) requires the first byte instruction code, thus returning to normal operation. It is recommended to input FFh/3FFh on IOO for the next instruction (8/10 clocks), to ensure M4 = 1 and return the device to normal operation.



Byte1

A23-16

A15-8

A7-0

M7-0*

The number of dummy clocks can be set by LC bit

Dummv

HOLD#(103)-



DTR Fast Read Quad I/O with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

The DTR Fast Read Quad I/O instruction can also be used to access a specific portion within a page by issuing a "Set Burst with Wrap" (77H) command prior to EDH. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following EDH commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8, 16, 32 or 64-byte section of a 256-byte page. The output data starts at the initial address specified in the instruction, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around to the beginning boundary automatically until CS# is pulled high to terminate the command.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands.

DTR Fast Read Quad I/O (EDH) in QPI Mode

The DTR Fast Read Quad I/O instruction is also supported in QPI mode, as shown in Figure 16b. In QPI mode, the "Continuous Read Mode" bits M7-0 are also considered as dummy clocks. In the default setting, the data output will follow the Continuous Read Mode bits immediately.

"Continuous Read Mode" feature is also available in QPI mode for Fast Read Quad I/O instruction. Please refer to the description on previous pages.

"Wrap Around" feature is not available in QPI mode for DTR Fast Read Quad I/O instruction. To perform a read operation with fixed data length wrap around in QPI mode, a dedicated "Burst Read with Wrap" (OCH) instruction must be used. Please refer to COH command for details.

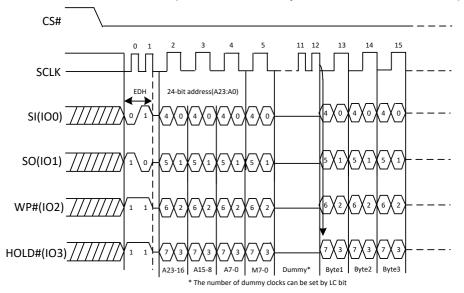


Figure 17b. DTR Fast Read Quad I/O (Initial instruction or previous M5-4≠10, QPI Mode)



5.4. Memory Program

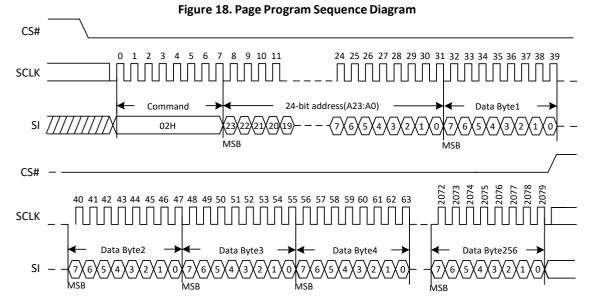
5.4.1. Page Program (02H)

The Page Program (PP) command is for programming the memory. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command.

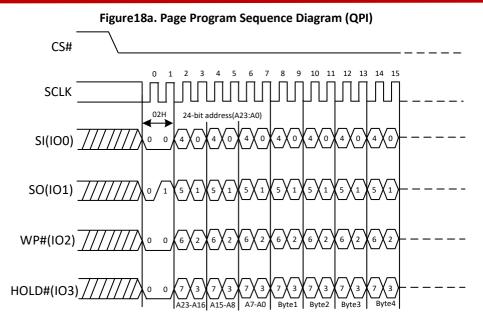
The Page Program (PP) command is entered by driving CS# Low, followed by the command code, three address bytes and at least one data byte on SI. If the 8 least significant address bits (A7-A0) are not all zero, all transmitted data that goes beyond the end of the current page are programmed from the start address of the same page (from the address whose 8 least significant bits (A7-A0) are all zero). CS# must be driven low for the entire duration of the sequence. The Page Program command sequence: CS# goes low \rightarrow sending Page Program command \rightarrow 3-byte address on SI \rightarrow at least 1 byte data on SI \rightarrow CS# goes high. The command sequence is shown in Figure17. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Page Program cycle (whose duration is tPP) is initiated. While the Page Program cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Page Program (PP) command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) is not executed.









5.4.2. Quad Page Program (32H)

The Quad Page Program command is for programming the memory using four pins: IOO, IO1, IO2, and IO3. To use Quad Page Program, the Quad Enable bit in status register Bit9 must be set (QE=1). A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command. The Quad Page Program command is entered by driving CS# Low, followed by the command code (32H), three address bytes and at least one data byte on IO pins.

The command sequence is shown in Figure 18. If the 8 least significant address bits (A7-A0) are not all zero, all transmitted data that goes beyond the end of the current page are programmed from the start address of the same page (from the address whose 8 least significant bits (A7-A0) are all zero). If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Quad Page Program command will not be executed.

As soon as CS# is driven high, the self-timed Quad Page Program cycle (whose duration is tPP) is initiated. While the Quad Page Program cycle is in progress, the Status Register can be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Quad Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Quad Page Program command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) will not be executed.

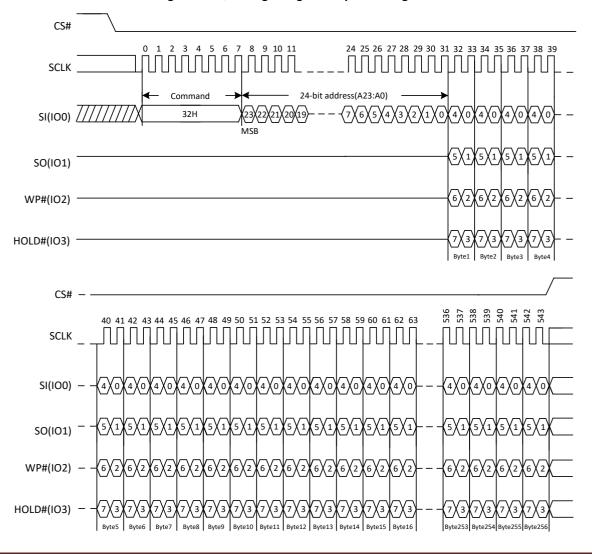


Figure 19. Quad Page Program Sequence Diagram

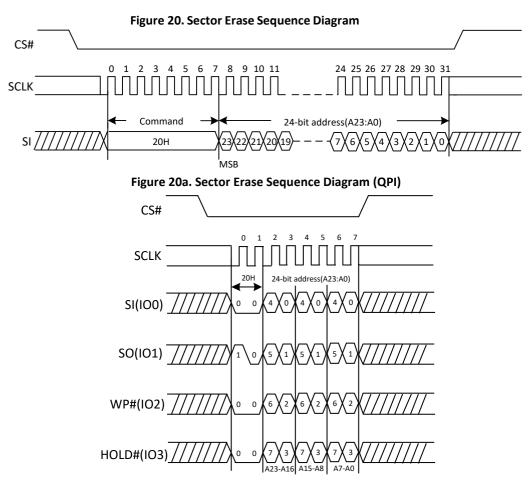


5.5. Memory Erase

5.5.1. Sector Erase (20H)

The Sector Erase (SE) command is for erasing all the data of the chosen sector. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Sector Erase command. The Sector Erase (SE) command is entered by driving CS# low, followed by the command code, and 3-address byte on SI. Any address inside the sector is a valid address for the Sector Erase (SE) command.

The Sector Erase command sequence: CS# goes low \rightarrow sending Sector Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 19. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the Sector Erase (SE) command will not be executed. As soon as CS# is driven high, the self-timed Sector Erase cycle (whose duration is tSE) is initiated. While the Sector Erase cycle is in progress, the Status Register can be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Sector Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A Sector Erase (SE) command applied to a sector which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bit (see Table 1.0 & 1.1) will not be executed.

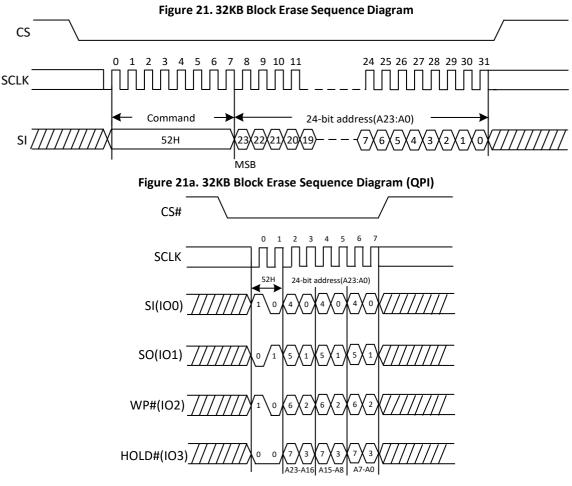




5.5.2. 32kB Block Erase (52H)

The 32KB Block Erase (BE) command is for erasing all the data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the 32KB Block Erase command. The 32KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI, driving CS# high. Any address inside the block is a valid address for the 32KB Block Erase (BE) command.

The 32KB Block Erase command sequence: CS# goes low \rightarrow sending 32KB Block Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 20. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 32KB Block Erase (BE) command will not be executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is tBE1) is initiated. While the Block Erase cycle is in progress, the Status Register can be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 32KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bits (see Table 1.0 & 1.1) will not be executed.

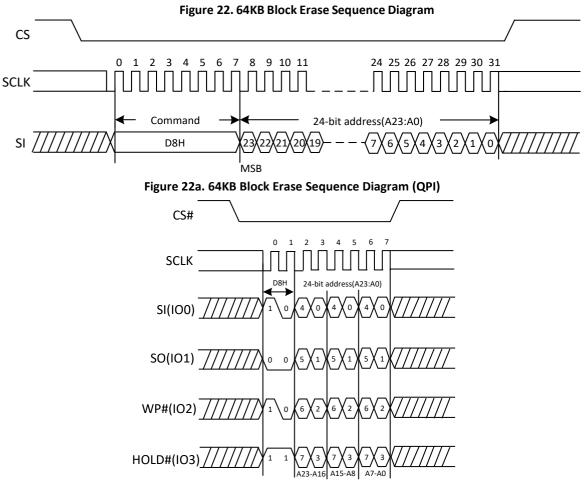




5.5.3. 64kB Block Erase (D8H)

The 64KB Block Erase (BE) command is for erasing all the data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit, before sending the 64KB Block Erase command. The 64KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI, driving CS# high. Any address inside the block is a valid address for the 64KB Block Erase (BE) command.

The 64KB Block Erase command sequence: CS# goes low \rightarrow sending 64KB Block Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 21. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 64KB Block Erase (BE2) command will not be executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is tBE) is initiated. While the Block Erase cycle is in progress, the Status Register can be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 64KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bits (see Table 1.0 & 1.1) will not be executed.

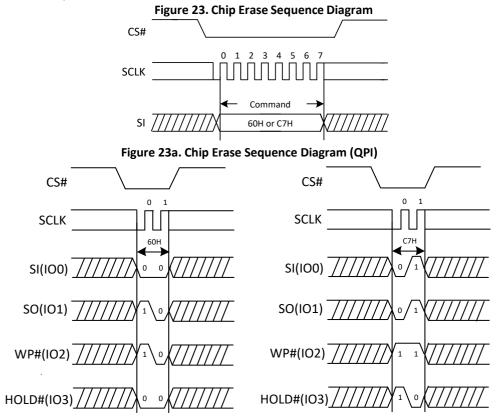




5.5.4. Chip Erase (60H or C7H)

The Chip Erase (CE) command is for erasing all the data of the chip. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit, before sending the Chip Erase command .The Chip Erase (CE) command is entered by driving CS# Low, followed by the command code on SI.

The Chip Erase command sequence: CS# goes low \rightarrow sending Chip Erase command \rightarrow CS# goes high. The command sequence is shown in Figure 22. CS# must be driven high after the eighth bit of the command code has been latch in, otherwise the Chip Erase command will not be executed. As soon as CS# is driven high, the self-timed Chip Erase cycle (whose duration is tCE) is initiated. While the Chip Erase cycle is in progress, the Status Register can be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Chip Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Chip Erase (CE) command is ignored if one or more sectors are protected.



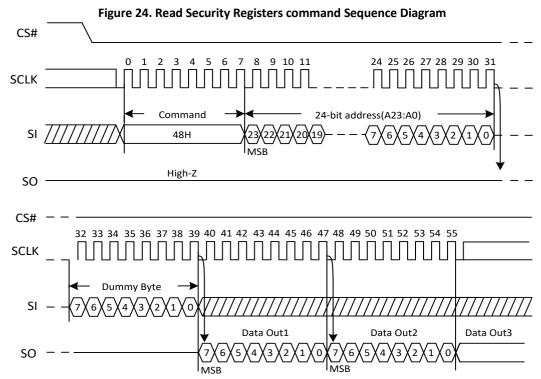


5.6. Security Register

5.6.1. Read Security Register (48H)

The Read Security Registers command is similar to Fast Read command. The command is followed by a 3byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fC, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. Once the A9-A0 address reaches the last byte of the register (Byte 3FFH), it will reset to 000H, the command is completed by driving CS# high.

| ADDRESS | A23-A16 | A15-A12 | A11-A10 | A9-A0 |
|---------------------|---------|---------|---------|--------------|
| Security Register 1 | 00h | 0001b | 00 | Byte Address |
| Security Register 2 | 00h | 0010b | 00 | Byte Address |



Note: The Byte Address A2-A0 must be 000.

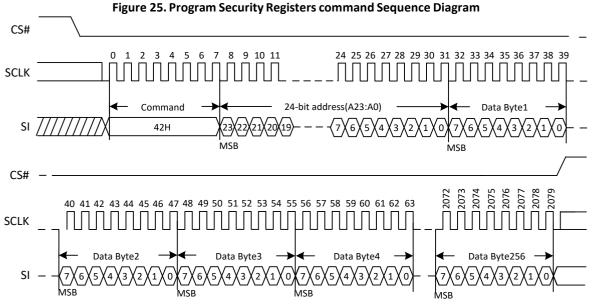
5.6.2. Program Security Register (42H)

The Program Security Registers command is similar to the Page Program command. It allows from 1 to 256 bytes Security Registers data to be programmed. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Program Security Registers command. The Program Security Registers command is entered by driving CS# Low, followed by the command code (42H), three address bytes and at least one data byte on SI. As soon as CS# is driven high, the self-timed Program Security Registers cycle (whose duration is tPP) is initiated. While the Program Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Program Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

If the Security Registers Lock Bit (LB1,LB2) is set to 1, the corresponding Security Registers (#1, #2) will be permanently locked. Program Security Registers command will be ignored.

| ADDRESS | A23-A16 | A15-A12 | A11-A10 | A9-A0 |
|---------------------|---------|---------|---------|--------------|
| Security Register 1 | 00h | 0001b | 00 | Byte Address |
| Security Register 2 | 00h | 0010b | 00 | Byte Address |





Note: When performing program security register or erase security register, program erase suspend (op code is 75H/B0H) is not allowed, if issuing suspend op code during program or erase security register, the device may enter into malfunction.

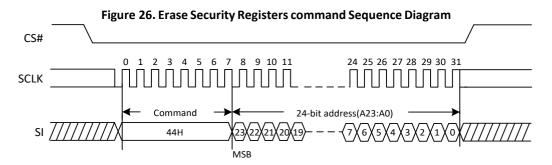
5.6.3. Erase Security Register (44H)

The device provides 2x1024-byte Security Registers which can be erased per 1024-byte at a time. These registers may be used by the system manufacturers to store security and other important information separately from the main memory array.

The Erase Security Registers command is similar to Sector/Block Erase command. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit.

The Erase Security Registers command sequence: CS# goes low \rightarrow sending Erase Security Registers Command \rightarrow CS# goes high. The command sequence is shown in Figure 25. CS# must be driven high after the eighth bit of the command code has been latched in, otherwise the Erase Security Registers command is not executed. As soon as CS# is driven high, the self-timed Erase Security Registers cycle (whose duration is tSE) is initiated. While the Erase Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Erase Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Security Registers Lock Bit (LB1,LB2) in the Status Register can be used to OTP protect the security registers. Once the LB bit is set to 1, the corresponding Security Registers (#1, #2) will be permanently locked; the Erase Security Registers command will be ignored.

| ADDRESS | A23-A16 | A15-A12 | A11-A10 | A9-A0 |
|---------------------|---------|---------|---------|------------|
| Security Register 1 | 00h | 0001b | 00 | Don't care |
| Security Register 2 | 00h | 0010b | 00 | Don't care |



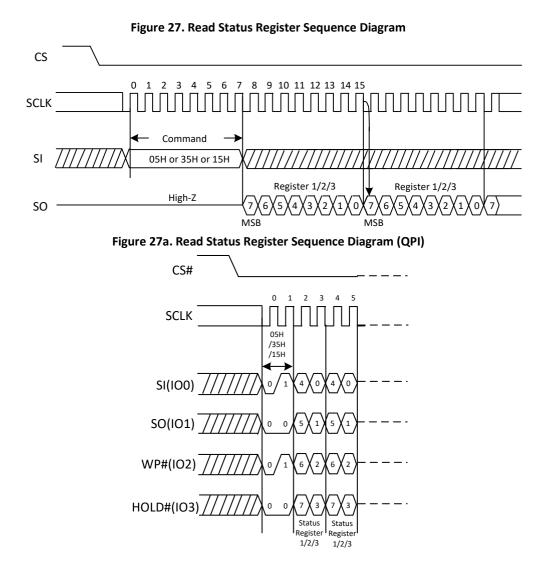
Note: When performing program security register or erase security register, program erase suspend (op code is 75H/B0H) is not allowed, if issuing suspend op code during program or erase security register, the device may enter into malfunction.



5.7. Status Register

5.7.1. Read Status Register (05H or 35H or 15H)

The Read Status Register (RDSR) command is for reading the Status Register. The Status Register can be read at any time, even while a Program, Erase or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new command to the device. It is also possible to read the Status Register continuously. For command code "05H", the SO will output Status Register bits S7~S0. For the command code "35H", the SO will output Status Register bits S15~S8. For the command code "15H", the SO will output Status Register bits S23~S16.



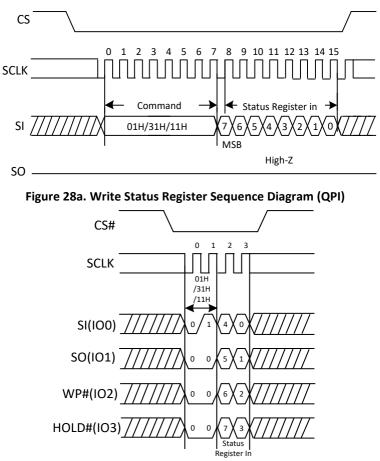


5.7.2. Write Status Register (01H or 31H or 11H)

The Write Status Register (WRSR) command allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) command must previously have been executed. After the Write Enable (WREN) command has been decoded and executed, the device sets the Write Enable Latch (WEL).

The Write Status Register (WRSR) command has no effect on S20, S19, S16, S13, S1 and S0 of the Status Register. CS# must be driven high after the eighth bit of the data byte has been latched in. If not, the Write Status Register (WRSR) command is not executed. As soon as CS# is driven high, the self-timed Write Status Register cycle (whose duration is tW) is initiated. While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Write Status Register cycle, and is 0 when it is completed. When the cycle is completed, the Write Enable Latch (WEL) is reset.

The Write Status Register (WRSR) command allows the user to change the values of the Block Protect (BP4, BP3, BP2, BP1, BP0) bits, to define the size of the area that is to be treated as read-only, as defined in Table 1.0 & 1.1 The Write Status Register (WRSR) command also allows the user to set or reset the Status Register Protect (SRP) bit in accordance with the Write Protect (WP#) signal. The Status Register Protect (SRP) bit and Write Protect (WP#) signal allow the device to be put in the Hardware Protected Mode. The Write Status Register (WRSR) command is not executed once the Hardware Protected Mode is entered. For command code "01H", the SI will input Status Register bits S7~S0. For the command code "31H", the SI will input Status Register bits S15~S8. For the command code "11H", the SI will input Status Register bits S23~S16.





Note:

1. If issue op code as 06H+50H+01H, this kind of op code combination will write the non-volatile register; We strongly suggest to issue op code separately, either 06H+01H or 50H+01H;

2. In order to be compatible with last generation products, 01H op code can also be use to write 2 bytes in one command sequence at the same time , that means 01H + byte0 +byte1 to write SR15~SR0.



5.8. Deep Power-Down

5.8.1. Deep Power-Down (B9H)

Executing the Deep Power-Down (DP) command is the only way to put the device in the lowest power consumption mode (the Deep Power-Down Mode). It can also be used as an extra software protection mechanism, since in this mode, the device ignores all Write, Program and Erase commands. Driving CS# high deselects the device, and puts the device in the Standby Mode (if there is no internal cycle currently in progress). But the Standby Mode is different from the Deep Power-Down Mode. The Deep Power-Down Mode can only be entered by executing the Deep Power-Down (DP) command. Once the flash memory has entered the Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down and Read Device ID (RDI) command (ABH) and Software Reset(66H + 99H). These commands release the device from the Deep Power-Down Mode.

The Deep Power-Down Mode automatically stops at Power-Off, and the device always Power-Up in the Standby Mode. The Deep Power-Down (DP) command is entered by driving CS# low, followed by the command code on SI, driving CS# high.

The Deep Power-Down command sequence: CS# goes low \rightarrow sending Deep Power-Down command \rightarrow CS# goes high. The command sequence is shown in Figure 28. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Deep Power-Down (DP) command will not be executed. As soon as CS# is driven high, it requires a time duration of tDP before the supply current is reduced to ICC2 and the Deep Power-Down Mode is entered. Any input of Deep Power-Down (DP) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.

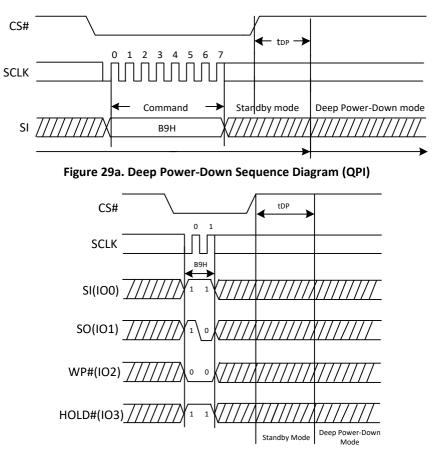


Figure 29. Deep Power-Down Sequence Diagram



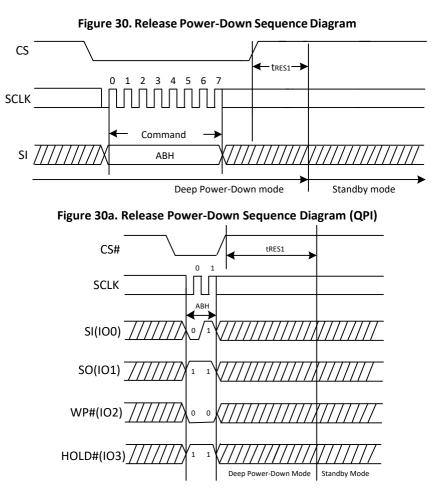
5.8.2. Release From Deep Power-Down (ABH)

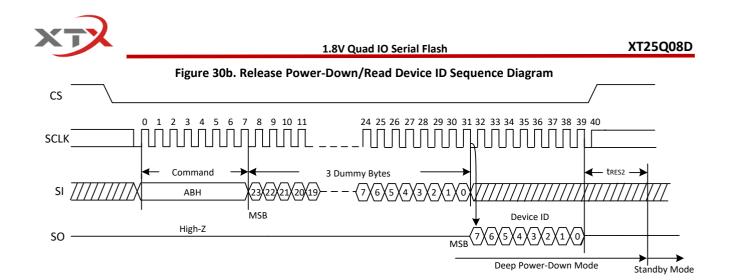
The Release from Deep Power-Down and Read Device ID command is a multi-purpose command. It can be used to release the device from Deep Power-Down Mode or obtain the devices electronic identification (ID) number.

To release the device from Deep Power-Down Mode, the command is issued by driving the CS# pin low, shifting the instruction code "ABH" and driving CS# high as shown in Figure 29. Release from Deep Power-Down Mode will take the time duration of tRES1 (See AC Characteristics) before the device resume to normal state and other command are accepted. The CS# pin must remain high during the tRES1 time duration.

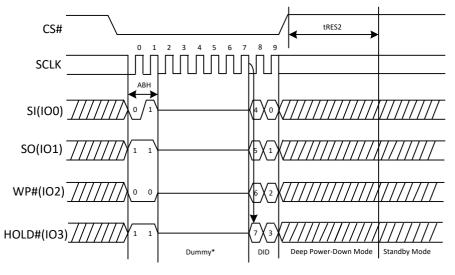
When the command is used only to obtain the Device ID while the flash memory is not in Deep Power-Down Mode, the command is initiated by driving the CS# pin low and shifting the instruction code "ABH" followed by 3 dummy bytes. The Device ID bits are then shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure29b. The Device ID value is listed in Manufacturer and Device Identification table. The Device ID can be read continuously. The command is completed by driving CS# high.

When the command is used to release the device from Deep Power-Down Mode and obtain the Device ID, the command is the same as previously described, and shown in Figure 29b, except that after CS# is driven high it must remain high for a time duration of tRES2 (See AC Characteristics). After this time duration the device will resume to normal mode and other command will be accepted. If the Release from Deep Power-Down and Read Device ID command is issued while an Erase, Program or Write cycle is in process (when WIP equal 1) the command will be ignored and will not affect the current cycle.











5.9. Software Reset

5.9.1. Enable Reset (66H) and Reset (99H)

If the Reset command is accepted, any on-going internal operation will be terminated and the device will return to its default power-on state and lose all the current volatile settings, such as Volatile Status Register bits, Write Enable Latch status (WEL), Read Parameter setting (P7-P0) and Wrap Bit Setting (W6-W4).

The "Reset (99H)" command sequence as follow: CS# goes low \rightarrow Sending Enable Reset command \rightarrow CS# goes high \rightarrow CS# goes low \rightarrow Sending Reset command \rightarrow CS# goes high. Once the Reset command is accepted by the device, the device will take approximately tRST_R to reset. During this period, no command will be accepted. Data corruption may happen if there is an on-going internal Erase or Program operation when Reset command sequence is accepted by the device. It is recommended to check the BUSY bit and the SUS bit in Status Register before issuing the Reset command sequence.

The Enable Reset (66H) command must be issued prior to a Reset(99H) command and any other commands can't be inserted between them. Otherwise, Enable Reset (66H) command will be cleared.

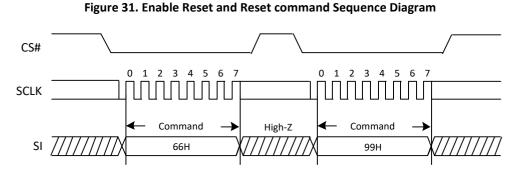
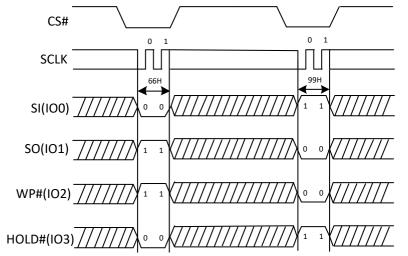


Figure 31a. Enable Reset and Reset command Sequence Diagram (QPI)

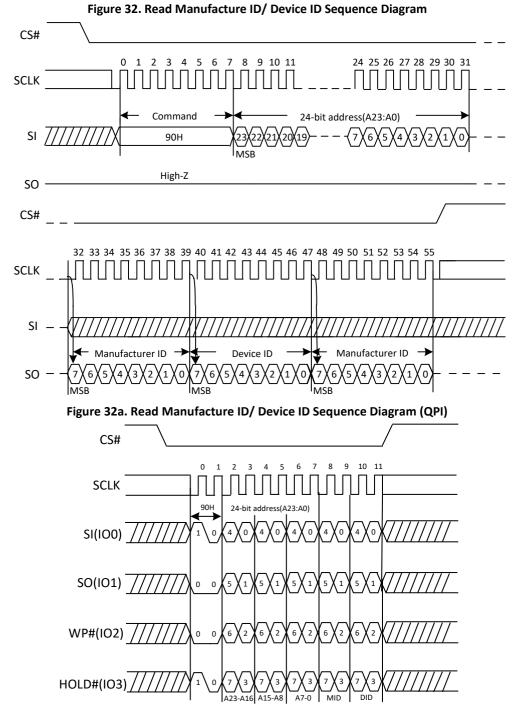




5.10. Read ID

5.10.1. Read Manufacture ID/ Device ID (90H)

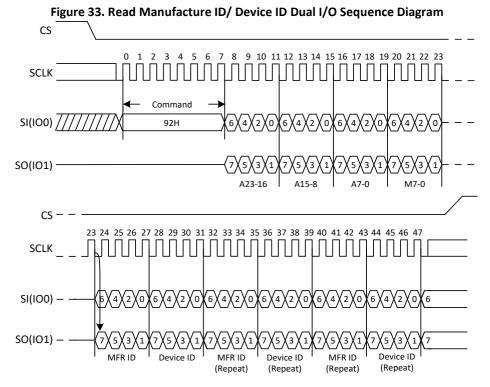
The command is initiated by driving the CS# pin low and shifting the command code "90H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first is shown in Figure 31. If the 24-bit address is initially set to 000001H, the Device ID will be read first.





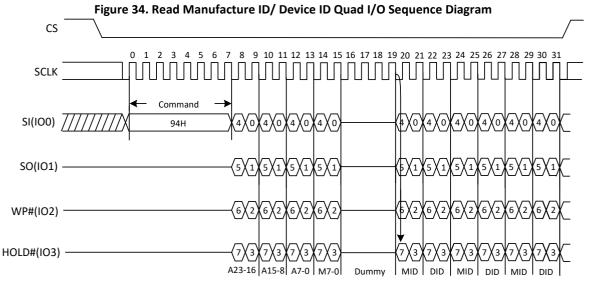
5.10.2. Read Manufacture ID/ Device ID Dual I/O (92H)

The command is initiated by driving the CS# pin low and shifting the command code "92H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 32 If the 24-bit address is initially set to 000001H, the Device ID will be read first.



5.10.3. Read Manufacture ID/ Device ID Quad I/O (94H)

The command is initiated by driving the CS# pin low and shifting the command code "94H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first is shown in Figure 33. If the 24-bit address is initially set to 000001H, the Device ID will be read first.

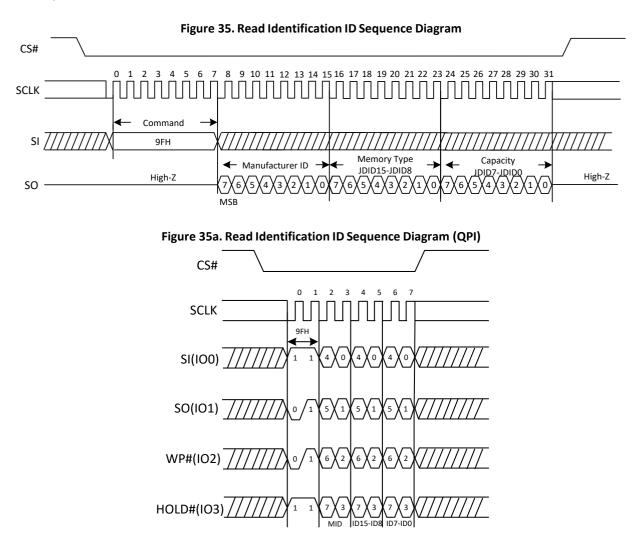




5.10.4. Read Identification (9FH)

The Read Identification (RDID) command allows the 8-bit manufacturer identification to be read, followed by two bytes of device identification. The device identification indicates the memory type in the first byte, and the memory capacity of the device in the second byte. Any Read Identification (RDID) command while an Erase or Program cycle is in progress will not be decoded, and has no effect on the cycle that is in progress. The Read Identification (RDID) command should not be issued while the device is in Deep Power-Down Mode.

The device is first selected by driving CS# to low. Then, the 8-bit command code for the command is shifted in. This is followed by the 24-bit manufacture identification and device identification, stored in the memory, being shifted out on Serial Data Output, each bit being shifted out during the falling edge of Serial Clock. The command sequence is shown in Figure 34. The Read Identification (RDID) command is terminated by driving CS# to high at any time during data output. When CS# is driven high, the device is put in the Standby Mode. Once in the Standby Mode, the device waits to be selected, so that it can receive, decode and execute commands.



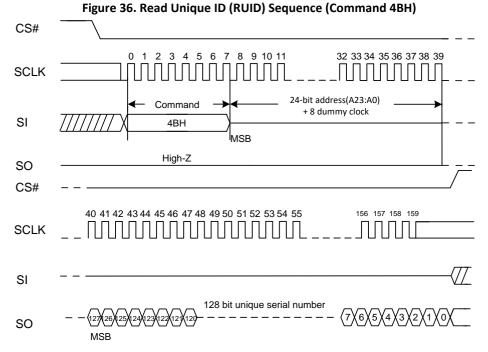


5.10.5. Read Unique ID (4BH)

The Read Unique ID command accesses a factory-set read-only 128bit number that is unique to each device. The Unique ID can be used in conjunction with user software methods to help prevent copying or cloning of a system.

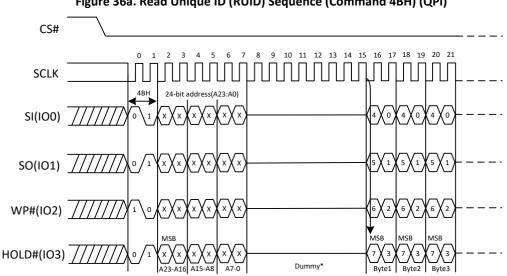
The Read Unique ID command sequence: CS# goes low \rightarrow sending Read Unique ID command \rightarrow 4 dummy bytes \rightarrow 128bit Unique ID Out \rightarrow CS# goes high.

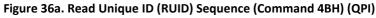
The command sequence is shown below.



Read Unique ID (4BH) in QPI mode

The Read Unique ID command is also supported in QPI mode. See Figure 35a. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8.



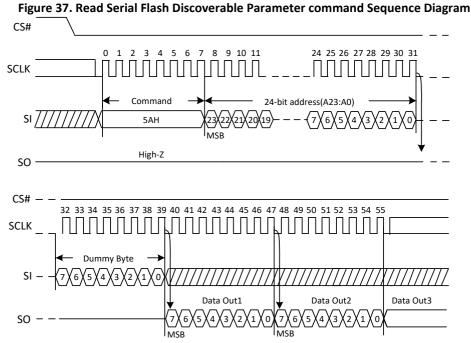


^{*}Set Read Parameters command (C0H) can set the number of dummy cycles



5.10.6. Read SFDP (5AH)

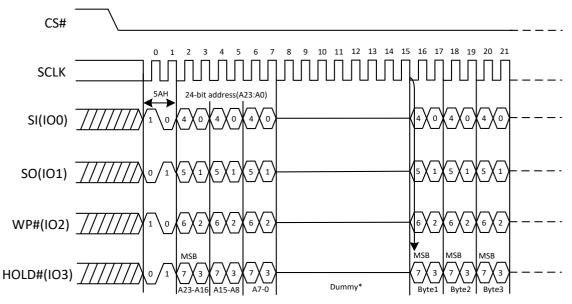
The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI. SFDP is a standard of JEDEC Standard No.216.



Note: A23-A8 = 0, A7-A0 is the starting byte address for 256-byte SFDP Register.

Read Serial Flash Discoverable Parameter (5AH) in QPI mode

The Read Serial Flash Discoverable Parameter command is also supported in QPI mode. See Figure 36a. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8.





*Set Read Parameters Command (COH) can set the number of dummy clocks



Table 3. Parameter Table (0): Signature and Parameter Identification Data Values

| Description | Comment | Add(H) | DW Add | Data | Data |
|--|--|--------|--------|------|------|
| | | (Byte) | (Bit) | | |
| SFDP Signature | Fixed:50444653H | 00H | 07:00 | 53H | 53H |
| | | 01H | 15:08 | 46H | 46H |
| | | 02H | 23:16 | 44H | 44H |
| | | 03H | 31:24 | 50H | 50H |
| SFDP Minor Revision Number | Start from 00H Follow JESD216B standard | 04H | 07:00 | 06H | 06H |
| SFDP Major Revision Number | Start from 01H Follow JESD216B standard | 05H | 15:08 | 01H | 01H |
| Number of Parameters Headers | Start from 00H | 06H | 23:16 | 01H | 01H |
| Unused | Contains 0xFFH and can never be changed | 07H | 31:24 | FFH | FFH |
| ID number (JEDEC) | 00H: It indicates a JEDEC specified header | 08H | 07:00 | 00H | 00H |
| Parameter Table Minor Revision Number | Start from 0x00H Follow JESD216B standard | 09H | 15:08 | 06H | 06H |
| Parameter Table Major Revision Number | Start from 0x01H Follow JESD216B standard | 0AH | 23:16 | 01H | 01H |
| Parameter Table Length | How many DWORDs in the | OBH | 31:24 | 10H | 10H |
| (in double word) | Parameter table | | | | |
| Parameter Table Pointer (PTP) | First address of JEDEC Flash | 0CH | 07:00 | 30H | 30H |
| | Parameter table | 0DH | 15:08 | 00H | 00H |
| | | 0EH | 23:16 | 00H | 00H |
| Unused | Contains 0xFFH and can never be changed | OFH | 31:24 | FFH | FFH |
| ID Number (XTX Manufacturer ID) | It is indicates XTX manufacturer ID | 10H | 07:00 | ОВН | ОВН |
| Parameter Table Minor Revision | Start from 0x00H | 11H | 15:08 | 01H | 01H |
| Parameter Table Major Revision Number | Start from 0x01H | 12H | 23:16 | 01H | 01H |
| Parameter Table Length | How many DWORDs in the | 13H | 31:24 | 03H | 03H |
| (in double word) | Parameter table | | | | |
| Parameter Table Pointer (PTP) | First address of XTX Flash Parameter | 14H | 07:00 | 90H | 90H |
| | table | 15H | 15:08 | 00H | 00H |
| | | 16H | 23:16 | 00H | 00H |
| Unused | Contains 0xFFH and can never be changed | 17H | 31:24 | FFH | FFH |



Parameter Table (1): JEDEC Flash Parameter Tables

| Description | Comment | Add(H) | DW Add | Data | Data |
|--|---|---------|--------|--------|------|
| | | (Byte) | (Bit) | | |
| Block/Sector Erase Size | e Size 00: Reserved; 01: 4KB erase; 10: Reserved; 11: Not support 4KB erase | | 01:00 | 01b | |
| Write Granularity | 0: Buffer size = 1Byte or <64Byte(32 Words) 1: Buffer Size = 64Byte(32 Words) or larger | | 02 | 1b | |
| Volatile Status Register Block Protect bits | 0: Nonvolatile status bit, support 06H and 50H 1: Volatile status bit | 30H | 03 | Ob | E5H |
| Write Enable Opcode Select for Writ- ing to Volatile Status Registers | 0: Use 50H Opcode, 1: Use 06H Opcode, Note: If target flash status register is nonvolatile, then bits 3 and 4 must be set to 00b. | | 04 | Ob | |
| Unused | Contains 111b and can never be changed | | 07:05 | 111b | |
| 4KB Erase Opcode | | 31H | 15:08 | 20H | 20H |
| (1-1-2) Fast Read | 0 = NOT supported 1 = supported | | 16 | 1b | |
| Address Bytes Number used in ad- dressing flash array | 00: 3Byte only, 01: 3 or 4Byte, 10: 4Byte only, 11: Reserved | | 18:17 | 00b | |
| Double Transfer Rate (DTR) clocking | 0 = NOT supported 1 = supported | 32H | 19 | 1b | F9H |
| (1-2-2) Fast Read | 0 = NOT supported 1 = supported | | 20 | 1b | |
| (1-4-4) Fast Read | 0 = NOT supported 1 = supported | | 21 | 1b | |
| (1-1-4) Fast Read | 0 = NOT supported 1 = supported | | 22 | 1b | |
| Unused | | | 23 | 1b | |
| Unused | | 33H | 31:24 | FFH | FFH |
| Flash Memory Density | | 37H:34H | 31:00 | 007FFF | FH |
| (1-4-4) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support 0 0100b: 4 Dummy Clocks (M7-M0 excluded) | 38H | 04:00 | 00100b | 44H |
| (1-4-4) Fast Read Number of Mode Bits | 000b:Mode Bits not support 010b: 8bit Mode Bits = 2 Dummy Clocks (M7-M0) | | 07:05 | 010b | |
| (1-4-4) Fast Read Opcode | | 39H | 15:08 | EBH | EBH |
| (1-1-4) Fast Read Number of Wait states | 1-1-4) Fast Read Number of Wait 0 0000b: Wait states (Dummy Clocks) | | 20:16 | 01000b | 08H |
| (1-1-4) Fast Read Number of Mode Bits | | 1 | 23:21 | 000b | 1 |
| (1-1-4) Fast Read Opcode | | 3BH | 31:24 | 6BH | 6BH |



| Description | Comment | Add(H) (Byte) | DW Add (Bit) | Data | Data |
|---|--|------------------|-----------------|--------|-------|
| (1-1-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support | | 04:00 | 01000b | |
| (1-1-2) Fast Read Number of Mode Bits | 0 1000b: 8 Dummy Clocks | | 07:05 | 000b | 08H |
| (1-1-2) Fast Read Opcodex | | 3DH | 15:08 | 3BH | 3BH |
| (1-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support (M7-M0 excluded) | ЗЕН | 20:16 | 00000b | 80H |
| (1-2-2) Fast Read Number of Mode Bits | 000b:Mode Bits not support 100b: 8bit Mode Bits = 4 Dummy Clocks (M7-M0) | JLII | 23:21 | 100b | |
| (1-2-2) Fast Read Opcode | | 3FH | 31:24 | BBH | BBH |
| (2-2-2) Fast Read | 0 = NOT supported 1 = supported | | 00 | Ob | |
| Unused | | 40H | 03:01 | 111b | FEH |
| (4-4-4) Fast Read | 0 = NOT supported 1 = supported | | 04 | 1b | |
| Unused | | | 07:05 | 111b | |
| Unused | | 43H:41H | 31:08 | 0xFFH | 0xFFH |
| Unused | | 45H:44H | 15:00 | 0xFFH | 0xFFH |
| (2-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support | 46H | 20:16 | 00000b | 00Н |
| (2-2-2) Fast Read Number of of Mode Bits | 000b: Mode Bits not support | | 23:21 | 000b | |
| (2-2-2) Fast Read Opcode | | 47H | 31:24 | FFH | FFH |
| Unused | | 49H:48H | 15:00 | 0xFFH | 0xFFH |
| (4-4-4) Fast Read Number of Wait states(QPI) | 0 0000b: Wait states (Dummy Clocks) not support 0 0110b: 6 Dummy Clocks | 4AH | 20:16 | 00110b | 46H |
| (4-4-4) Fast Read Number of Mode Bits | (M7-M0 excluded) 000b:Mode Bits not support 010b: 8bit Mode Bits = 2 Dummy Clocks (M7-M0) | 4411 | 23:21 | 010b | 4011 |
| (4-4-4) Fast Read Opcode | | 4BH | 31:24 | EBH | EBH |
| Erase Type 1 Size (4Kb) | Sector/block size=2^N Bytes 0x00b: this sector type don't exist | 4CH | 07:00 | 0CH | ОСН |
| Erase Type 1 Opcode | | 4DH | 15:08 | 20H | 20H |
| Erase Type 2 Size (32Kb) | Sector/block size=2^N Bytes 0x00b: this sector type don't exist | 4EH | 23:16 | 0FH | OFH |
| Erase Type 2 Opcode | | 4FH | 31:24 | 52H | 52H |
| Erase Type 3 Size (64Kb) | Sector/block size=2^N Bytes 0x00b: this sector type don't exist | 50H | 07:00 | 10H | 10H |
| Erase Type 3 Opcode | | 51H | 15:08 | D8H | D8H |
| Erase Type 4 Size (256Kb) | Sector/block size=2^N Bytes 0x00b: this sector type don't exist | 52H | 23:16 | 00H | 00H |
| Erase Type 4 Opcode | | 53H | 31:24 | FFH | FFH |



| Description | Comment | Add(H) (Byte) | DW Add (Bit) | Data | Data |
|-------------------------------------|------------------------------------|------------------|-----------------|----------|---------------|
| Multiplier from typical erase time | Erase Type n=1 | | 3:0 | 1000b | |
| to maximum erase time | | 54H:55H | | | |
| Erase Type 1 Erase, Typical time | Erase time=45ms/48ms | | 8:4 | 00010b | 1 |
| | | | 10:9 | 01b | |
| Erase Type 2 Erase, Typical time | Erase time=120ms/128ms | _ | 15:11 | 00111b | FEA5 3A28H |
| | | | 17:16 | 01b | |
| Erase Type 3 Erase, Typical time | Erase time=150ms/160ms | - | 22:18 | 01001b | |
| | | 56H:57H | 24:23 | 01b | |
| Erase Type 4 Erase, Typical time | Not exist | | 31:25 | 1111111b | |
| Multiplier from typical time to max | | | 3:0 | 0001b | |
| time for Page or Byte program | | 58H | | | 81H |
| Page Size | Page size=256Byte | | 7:4 | 1000b | |
| Page Program Typical time | Page program=350us/384us | 5011 | 13:8 | 100101b | |
| Byte Program Typical time, first | First Byte program=30us/32us | 59H | 15:14 | 11b | E5H |
| Byte | | | 18:16 | 100b | |
| Byte Program Typical time, | Additional Byte program=2.5us/3us | 5AH | 23:19 | 00010b | 14H |
| additional Byte | | | | | |
| Chip Erase, Typical time | Chip erase typical time=2.5s/2.56s | — 5вн | 30:24 | 0101001b | 29H |
| Reserved | | 501 | 31 | 0b | |
| Prohibited Operations During | | | 3:0 | 1000b | |
| Program Suspend | | 5СН | | | - A8H |
| Prohibited Operations During | | Seri | 7:4 | 1010b | |
| Erase Suspend | | | | | |
| Reserved | | | 8 | 0b | |
| Program Resume to Suspend | Interval=100us/128us | 5DH | 12:9 | 0001b | 62H |
| Interval | | - | | | - |
| Suspend in-progress program | max latency=20us/20us | _ | 15:13 | 011b | _ |
| max latency | | | 19:16 | 0110b | |
| Erase Resume to Suspend | Interval=100us/128us | 5EH | 23:20 | 0001b | 16H |
| Interval | | | | | |
| Suspend in-progress erase max | max latency=20us/20us | | 30:24 | 0110011b | |
| latency | | 5FH | | | 33H |
| Suspend / Resume supported | 0 = supported 1 = NOT supported | - | 31 | Ob | - |
| Program Resume Instruction | | 60H | 7:0 | 7AH | 7AH |
| Program Suspend Instruction | | 61H | 15:0 | 75H | 75H |
| Resume Instruction | | 62H | 23:16 | 7AH | 7AH |
| Suspend Instruction | | 63H | 31:24 | 75H | 75H |



| | | Add(H) | DW Add | | |
|--|---|--------|--------|----------|------|
| Description | Comment | (Byte) | (Bit) | Data | Data |
| Reserved | | | 1:0 | 11b | |
| Status Register Polling Device Busy | Use of legacy polling is supported by reading the Status Register with 05h instruction and checking WIP bit[0] | 64H | 7:2 | 111101b | F7H |
| Exit Deep Power-Down to next operation delay | Delay=3us/3us | 65H | 14:8 | 0100010b | A2H |
| Exit Deep Power-Down Instruction | | | 15 | 1b | |
| | АВН | | 22:16 | 1010101b | |
| Enter Deep Power-Down Instruction | | 66H | 23 | 1b | D5H |
| | В9Н | | 30:24 | 1011100b | |
| Deep Power-Down Supported | 0 = supported 1 = NOT supported | 67H | 31 | Ob | 5CH |
| 4-4-4 mode disable sequences | Issue FFH or 66/99H, set 1001b; If QPI not supported, set all bit to 0; | 6011 | 3:0 | 1001b | 19Н |
| 4-4-4 mode enable sequences | x_xxx1x: Issue instruction 38H; x_xxxx1: Set QE bit, then issue | 68H | 7:4 | 0001b | |
| | instruction 38H; If QPI not supported, set all bit to 0; | | 8 | Ob | |
| 0-4-4 mode supported | 0 = NOT supported 1 = supported | | 9 | 1b | |
| 0-4-4 Mode Exit Method | <pre>xx_xxx1b: Mode Bits[7:0] = 00h will ter- minate this mode at the end of the cur- rent read operation xx_x1xxb/1x_xxxxb: Reserved xx_1xxxb: Input Fh (mode bit reset) on IO0-IO3 for 8 clocks. This will terminate the mode prior to the next read opera- tion.</pre> | 69Н | 15:10 | 101101b | в6н |
| 0-4-4 Mode Entry Method | <pre>xxx1b: Mode Bits[7:0] = A5h Note: QE must be set prior to using this mode. x1xxb: Mode Bit[7:0]=AXH. 1xxxb: Reserved.</pre> | | 19:16 | 1101b | |
| Quad Enable Requirements | 100b: QE is bit 1 of status register 2. |] | 22:20 | 100b | 1 |
| (QER) | It is set via Write Status with two data bytes where bit 1 of the second byte is one. It is cleared via Write Status with two data bytes where bit 1 of the second byte is zero. Writing one byte to | 6AH | | | 4DH |
| | the status register does not modify sta- tus register 2. | | | | |
| RESET Disable | 1=Set Extended Configuration Register bit 4 to disable HOLD or RESET; 0=not support; | | 23 | Ob | |



| Reserved | | 6BH | 31:24 | 11111111b | FFH |
|--|---|-------|-------|-----------|-----|
| Volatile or Non-Volatile Register and Write Enable Instruction for Status Register 1 | x1x_xxxxb/1xx_xxxb: Reserved xxx_1xxxb: Non-Volatile/Volatile status register 1 powers-up to last written val- ue in the non-volatile status register, use instruction 06h to enable write to non- volatile status register. Volatile status register may be activated after power-up to override the non-volatile status regis- ter, use instruction 50h to enable write and activate the volatile status register. | (CII) | 6:0 | 1101000b | E8H |
| Reserved | | | 7 | 1b | |
| Soft Reset and Rescue Sequence Support | 66Н-99Н | 6DH | 13:8 | 010000b | 10H |
| Exit 4-Byte Addressing | | | 15:14 | 00b | |
| | | 6EH | 23:16 | 0000000b | 00H |
| Enter 4-Bye Addressing | | 6FH | 31:24 | 0000000b | 00H |



Parameter Table (2): XTX Flash Parameter Tables

| Description | Comment | Add(H) (Byte) | DW Add (Bit) | Data | Data |
|--|---|------------------|-----------------|---------------------|-------|
| Vcc Supply Maximum Voltage | 1600H=1.600V 1950H=1.950V 2000H=2.000V 2100H=2.100V 3600H=3.600V | 91H:90H | 15:00 | 2000H | 2000H |
| Vcc Supply Minimum Voltage | 1140H=1.140V 1650H=1.650V 2700H=2.700V | 93H:92H | 31:16 | 1650H | 1650H |
| HW Reset# pin | 0 = NOT supported 1 = supported | | 00 | 1b | |
| HW Hold# pin | 0 = NOT supported 1 = supported | | 01 | 1b | |
| Deep Power Down Mode | 0 = NOT supported 1 = supported | | 02 | 1b | |
| SW Reset | 0 = NOT supported 1 = supported | 95H:94H | 03 | 1b | F99FH |
| SW Reset Opcode | Should be issue Reset Enable(66H) before Reset command. | | 11:04 | 1001 1001b (99H) | |
| Program Suspend/Resume | 0 = NOT supported 1 = supported | | 12 | 1b | |
| Erase Suspend/Resume | 0 = NOT supported 1 = supported | | 13 | 1b | |
| Unused | | | 14 | 1b | |
| Wrap-Around Read mode | 0 = NOT supported 1 = supported | | 15 | 1b | |
| Wrap-Around Read mode Opcode | | 96H | 23:16 | 77H | 77H |
| Wrap-Around Read data length | 08H:support 8Byte wrap-around read 16H:8B&16Byte 32H:8B&16B&32Byte 64H:8B&16B&32B&64Byte | 97H | 31:24 | 64H | 64H |
| Individual block lock | 0 = NOT supported 1 = supported | | 00 | 1b | |
| Individual block lock bit (Volatile/Nonvolatile) | 0=Volatile 1=Nonvolatile | | 01 | Ob | |
| Individual block lock Opcode | | | 09:02 | 36H | |
| Individual block lock Volatile Protect bit default protect status | 0=protected 1=unprotected | 9BH:98H | 10 | Ob | E8D9H |
| Secured OTP | 0 = NOT supported 1 = supported | | 11 | 1b | |
| Read Lock | 0 = NOT supported 1 = supported | | 12 | Ob | |
| Permanent Lock | 0 = NOT supported 1 = supported | | 13 | 1b | |
| Unused | | | 15:14 | 11b | |
| Unused | | | 31:16 | FFFFH | FFFFH |



5.11. Advanced Data Protection

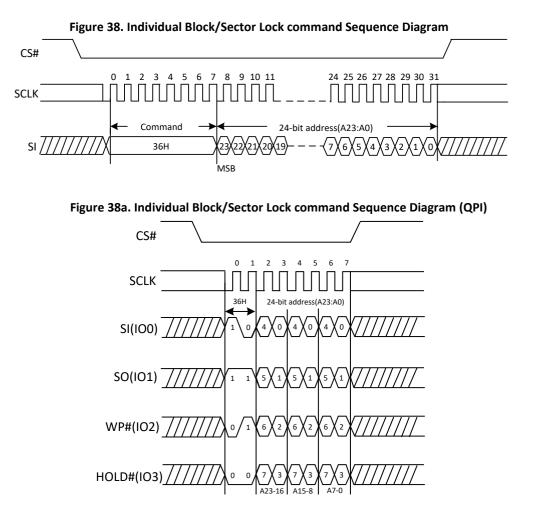
5.11.1. Individual Block/Sector Lock (36H)/Unlock (39H)/Read (3DH)

The individual block/sector lock provides an alternative way to protect the memory array from adverse Erase/Program. In order to use the Individual Block/Sector Locks, the WPS bit in Status Register-3 must be set to 1. If WPS=0, the write protection will be determined by the combination of CMP, BP (4:0) bits in the Status Register. The Individual Block/Sector Lock bits are volatile bits, the default values of which after device power up or after a Reset are 1.

The individual Block/Sector Lock command (36H) sequence: CS# goes low \rightarrow SI: Sending individual Block/Sector Lock command \rightarrow SI: Sending 24bits individual Block/Sector Lock Address \rightarrow CS# goes high. The command sequence is shown in Figure 37.

The individual Block/Sector Unlock command (39H) sequence: CS# goes low \rightarrow SI: Sending individual Block/Sector Unlock command \rightarrow SI: Sending 24bits individual Block/Sector Lock Address \rightarrow CS# goes high. The command sequence is shown in Figure 37a.

The Read individual Block/Sector lock command (3DH) sequence: CS# goes low \rightarrow SI: Sending Read individual Block/Sector Lock command \rightarrow SI: Sending 24bits individual Block/Sector Lock Address \rightarrow SO: The Block/Sector Lock Bit will out \rightarrow CS# goes high. If the least significant bit (LSB) is1, the corresponding block/sector is locked, if the LSB is 0, the corresponding block/sector is unlocked, Erase/Program operation can be performed. The command sequence is shown in Figure 37c.





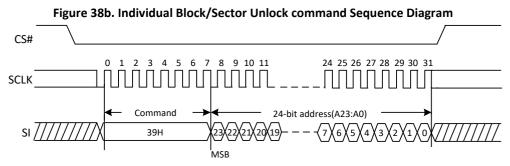


Figure 38c. Individual Block/Sector Unlock command Sequence Diagram (QPI)

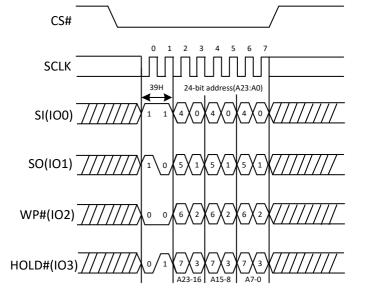


Figure 38d. Read Individual Block/Sector lock command Sequence Diagram

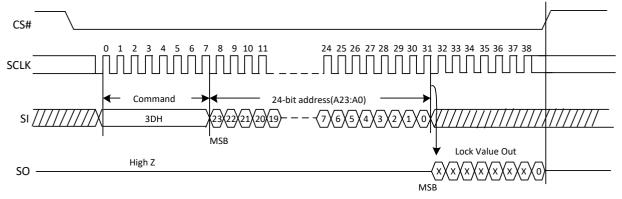
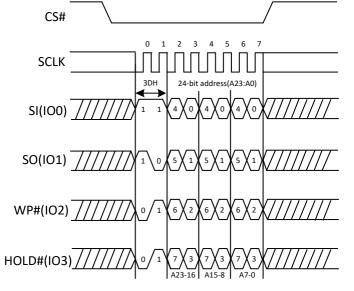




Figure 38e. Read Individual Block/Sector lock command Sequence Diagram (QPI)



5.11.2. Global Block/Sector Lock (7EH) or Unlock (98H)

All Block/Sector Lock bits can be set to 1 by the Global Block/Sector Lock command, or can set to 0 by the Global Block/Sector Unlock command.

The Global Block/Sector Lock command (7EH) sequence: CS# goes low \rightarrow SI: Sending Global Block/Sector Lock command \rightarrow CS# goes high. The command sequence is shown in Figure 38.

The Global Block/Sector Unlock command (98H) sequence: CS# goes low \rightarrow SI: Sending Global Block/Sector Unlock command \rightarrow CS# goes high. The command sequence is shown in Figure 38b.



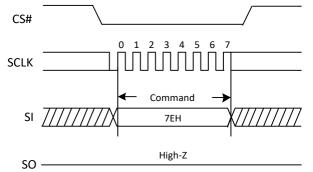


Figure39a. The Global Block/Sector Lock Sequence Diagram (QPI)

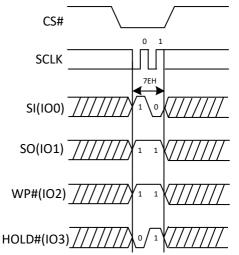




Figure 39b. The Global Block/Sector Unlock Sequence Diagram

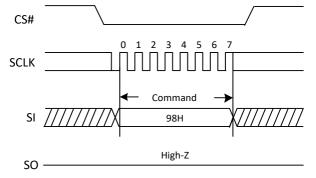
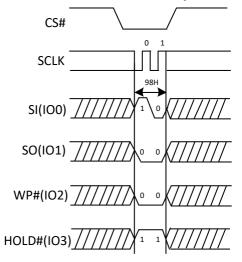


Figure 39c. The Global Block/Sector Unlock Sequence Diagram (QPI)





5.12. Suspend

5.12.1. Program Erase Suspend (75H/B0H)

The Program/Erase Suspend command "75H", allows the system to interrupt a page program or sector/block erase operation and then read data from any other sector or block. The Write Status Register command (01H, 31H, 11H) and Erase/Program Security Registers command (44H, 42H) and Erase commands (20H, 52H, D8H, C7H, 60H) and Page Program command (02H, 32H) are not allowed during Program suspend. The Write Status Register command (01H, 31H, 11H) and Erase Security Registers command (44H) and Erase commands (20H, 52H, D8H, C7H, 60H) are not allowed during Erase suspend. Program/Erase Suspend is valid only during the page program or sector/block erase operation. A maximum of time of "tSUS" (See AC Characteristics) is required to suspend the program/erase operation.

The Program/Erase Suspend command will be accepted by the device only if the SUS bit in the Status Register equal to 0 and WIP bit equal to 1 while a Page Program or a Sector or Block Erase operation is on-going. If the SUS bit equal to 1 or WIP bit equal to 0, the Suspend command will be ignored by the device. The WIP bit will be cleared from 1 to 0 within "tSUS" and the SUS bit will be set from 0 to 1 immediately after Program/Erase Suspend. A power-off during the suspend period will reset the device and release the suspend state. The command sequence is shown in Figure 39.

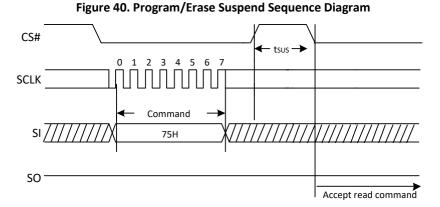
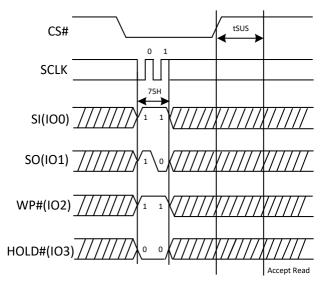


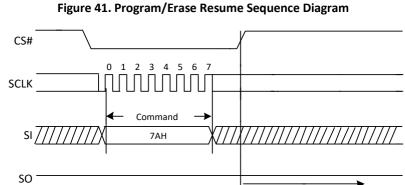
Figure 40a. Program/Erase Suspend Sequence Diagram(QPI)



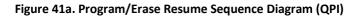


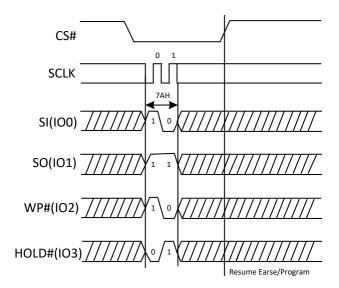
5.12.2. Program Erase Resume (7AH/30H)

The Program/Erase Resume command must be written to resume the program or sector/block erase operation after a Program/Erase Suspend command. The Program/Erase command will be accepted by the device only if the SUS bit equal to 1 and the WIP bit equal to 0. After issued the SUS bit in the status register will be cleared from 1 to 0 immediately, the WIP bit will be set from 0 to 1 within 200ns and the Sector or Block will complete the erase operation or the page will complete the program operation. The Program/Erase Resume command will be ignored unless a Program/Erase Suspend is active. The command sequence is shown in Figure 40.



Resume Erase/Program







5.13. Wrap

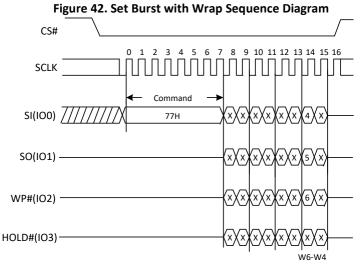
5.13.1. Set Burst With Wrap (77H)

The Set Burst with Wrap command is used in conjunction with "Quad I/O Fast Read (EBH)", "Quad I/O Word Fast Read (E7H)" and "Quad Read under DTR (EDH)" commands to access a fixed length of 8/16/32/64-byte section within a 256-byte page in standard SPI mode. The Set Burst with Wrap command sequence: CS# goes low \rightarrow Send Set Burst with Wrap command \rightarrow Send 24 dummy bits \rightarrow Send 8 bits "Wrap bits" \rightarrow CS# goes high

| W6,W5 | W4=0 | | W4=0 W4=1(default) | |
|-----------|-------------|-------------|--------------------|-------------|
| ••••,•••5 | Wrap Around | Wrap Length | Wrap Around | Wrap Length |
| 0,0 | Yes | 8-byte | No | N/A |
| 0,1 | Yes | 16-byte | No | N/A |
| 1,0 | Yes | 32-byte | No | N/A |
| 1,1 | Yes | 64-byte | No | N/A |

If the W6-W4 bits are set by the Set Burst with Wrap command, all the following "Quad I/O Fast Read (EBH)" and "Quad I/O Word Fast Read (E7H)" and "Quad Read under DTR (EDH)" command will use the W6-W4 setting to access the 8/16/32/64-byte section within any page. To exit the "Wrap Around" function and return to normal read operation, another Set Burst with Wrap command should be issued to set W4=1.

In QPI mode, the "Burst Read with Wrap (0CH)" command should be used to perform the Read Operation with "Wrap Around" feature. The Wrap Length set by W5-W6 in Standard SPI mode is still valid in QPI mode and can also be re-configured by "Set Read Parameters (C0H) command.



5.13.2. Set Read Parameters (C0H)

In QPI mode, to accommodate a wide range of applications with different needs for either maximum readfrequency or minimum data access latency, "Set Read Parameters (COH)" instruction can be used to configure the number of dummy clocks for "Fast Read (OBH)", "Fast Read Quad I/O (EBH)" & "Burst Read with Wrap (OCH)" instructions, and to configure the number of bytes of "Wrap Length" for the "Burst Read with Wrap (OCH)" instruction. In Standard SPI mode, the "Set Read Parameters (COH)" instruction is not accepted.

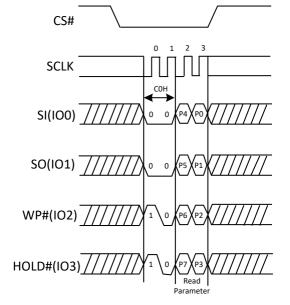
The dummy clocks for various Fast Read instructions in Standard/Dual/Quad SPI mode are fixed and will remain unchanged when the device is switched from Standard SPI mode to QPI mode and requires to be set again, prior to any OBh, EBh or OCh instructions. When the device is switched from QPI mode to SPI mode, the number of dummy clocks goes back to default.

The default "Wrap Length" after a power up or a Reset instruction is 8 bytes, the default number of dummy clocks is 8. The "Wrap Length" is set by W6-4 bit in the "Set Burst with Wrap (77H)" instruction in Standard SPI mode and by P1-P0 in the "Set Read Parameters (COH)" in the QPI mode. The Wrap Length set by P1-P0 in QPI mode is still valid in SPI mode and can also be re-configured by "Set Burst with Wrap (77H)".



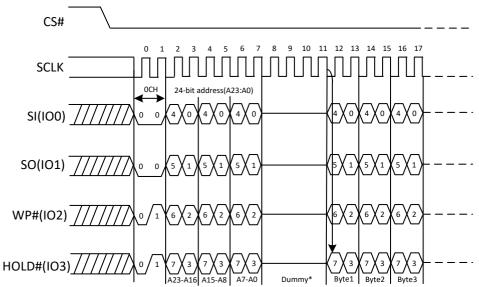
| P5-P4 | Dummy Clocks | Maximum Read Freq. | P1-P0 | Wrap Length |
|--------------|--------------|--------------------|-------|-------------|
| 0 0 | 4 | 80MHz | 0 0 | 8-byte |
| 01 | 4 | 80MHz | 01 | 16-byte |
| 10 | 6 | 108MHz | 10 | 32-byte |
| 11 (Default) | 8 | 108MHz | 11 | 64-byte |





5.13.3. Burst Read With Wrap (0CH)

The "Burst Read with Wrap (OCH)" command provides an alternative way to perform the read operation with "Wrap Around" in QPI mode. This command is similar to the "Fast Read (OBH)" command in QPI mode, except the addressing of the read operation will "Wrap Around" to the beginning boundary of the "Wrap Around" once the ending boundary is reached. The "Wrap Length" and the number of dummy clocks can be configured by the "Set Read Parameters (COH)" command.

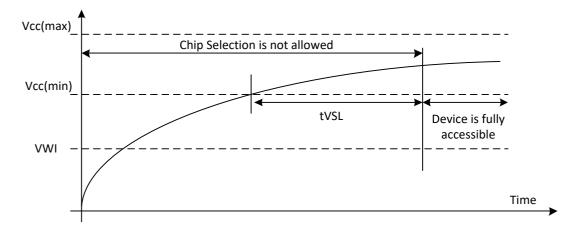






6. ELECTRICAL CHARACTERISTICS

6.1. Power-Down & Power-on Timing



Power-Up Timing and Write Inhibit Threshold

| Symbol | Parameter | Min | Max | Unit |
|------------------|-----------------------|-----|-----|------|
| t _{vsL} | VCC(min) To CS# Low | 200 | | us |
| V _{WI} | Write Inhibit Voltage | - | 1.5 | V |

6.2. Initial Delivery State

The device is delivered with the memory array erased: all bits are set to 1(each byte contains FFH). All Status Register bits except S22 bit are 0, S22 bit is 1.

6.3. Latch up Characteristics

| Parameter | Min | Max |
|--|--------|----------|
| Input Voltage Respect To VSS On I/O Pins | -1.0V | VCC+1.0V |
| VCC Current | -100mA | 100mA |

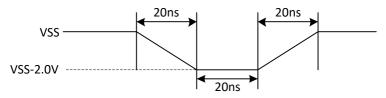


6.4. Absolute Maximum Ratings

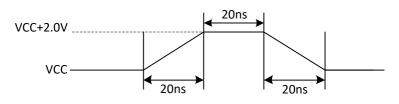
| Parameter | Value | Unit |
|-------------------------------|-------------|------|
| Ambient Operating Temperature | -40 to 85 | °C |
| Storage Temperature | -65 to 150 | °C |
| Output Short Circuit Current | 200 | mA |
| Applied Input/Output Voltage | -0.5 to 2.5 | V |
| VCC | -0.5 to 2.5 | V |

Input Test Waveform and Measurement Level

Maximum Negative Overshoot Waveform



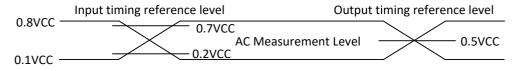
Maximum Positive Overshoot Waveform



6.5. Capacitance Measurement Condition

| Symbol | Parameter | Min. | Тур. | Max. | Unit | Conditions |
|--------|---------------------------------|------------------|--------|------|--------|------------|
| CIN | Input Capacitance | 6 | | pF | VIN=0V | |
| COUT | Output Capacitance | | | 8 | pF | VOUT=0V |
| CL | Load Capacitance | 30 | | pF | | |
| | Input Rise And Fall time | | | 5 | ns | |
| | Input Pulse Voltage | 0.1VCC to 0.8VCC | | V | | |
| | Input Timing Reference Voltage | 0.2VCC to 0.7VCC | | V | | |
| | Output Timing Reference Voltage | | 0.5VCC | | V | |

Absolute Maximum Ratings Diagram



Note: Input pulse rise and fall time are <5ns



6.6. DC Characteristics

(TA=-40°C~85°C,VCC=1.65~2.0V)

| Symbol | Parameter | Test Condition | Min. | Тур | Max. | Unit |
|--------|---------------------------------------|---|---------|-----|---------|------|
| ILI | Input Leakage Current | | | | ±2 | μΑ |
| ILO | Output Leakage Current | | | | ±2 | μA |
| ICC1 | Standby Current | CS#=VCC VIN=VCC or VSS | | 12 | 25 | μΑ |
| ICC2 | Standby Current (High Speed Mode) | CS#=VCC VIN=VCC or VSS | | 420 | 1000 | μΑ |
| ICC3 | Deep Power-Down Current | CS#=VCC VIN=VCC or VSS | | 0.3 | 5 | μΑ |
| | | CLK=0.1VCC/0.9VCC at 108MHz, Q=Open(*1,*2,*4 I/O) | | 10 | 18 | mA |
| ICC4 | Operating Current(Read) | CLK=0.1VCC/0.9VCC at 80MHz, Q=Open(*1,*2,*4 I/O) | | 7 | 14 | mA |
| | | CLK=0.1VCC/0.9VCC at 48MHZ, Q=Open(*1,*2,*4 I/O) | | 5 | 11 | mA |
| ICC5 | Operating Current(PP) | CS#=VCC | | 15 | 20 | mA |
| ICC6 | Operating Current(WRSR) | CS#=VCC | | 10 | 20 | mA |
| ICC7 | Operating Current(SE) | CS#=VCC | | 10 | 20 | mA |
| ICC8 | Operating Current(BE) | CS#=VCC | | 15 | 20 | mA |
| VIL | Input Low Voltage | | -0.5 | | 0.2VCC | V |
| VIH | Input High Voltage | | 0.7VCC | | VCC+0.4 | V |
| VOL | Output Low Voltage | IOL=100μA | | | 0.2 | V |
| VOH | Output High Voltage | IOH=-100μA | VCC-0.2 | | | V |

Note:

1. Typical values given for TA=25°C,Vcc=1.8V.

2. Value guaranteed by design and/or characterization, not 100% tested in production.



6.7. AC Characteristics

(TA=-40°C~85°C,VCC=1.65~2.0V, CL=30pF)

| Symbol | Parameter | Min. | Typ. ⁽²⁾ | Max. | Unit |
|----------------------|---|-------|---------------------|------|------|
| fC1 ^{Note3} | Serial Clock Frequency For: all commands in STR | D.C. | | 108 | MHz |
| | except Read (03H) | | | | |
| fC2 ^{Note3} | Serial Clock Frequency For: DTR instructions | D.C. | | 86 | MHz |
| fR | Serial Clock Frequency for Read Data(03H) | D.C. | | 80 | MHz |
| tCLH ⁽¹⁾ | Serial Clock High Time | 45%PC | | | ns |
| tCLL ⁽¹⁾ | Serial Clock Low Time | 45%PC | | | ns |
| tCLCH | Serial Clock Rise Time(Slew Rate) | 0.2 | | | V/ns |
| tCHCL | Serial Clock Fall Time(Slew Rate) | 0.2 | | | V/ns |
| tSLCH | CS# Active Setup Time | 5 | | | ns |
| tCHSH | CS# Active Hold Time | 5 | | | ns |
| tSHCH | CS# Not Active Setup Time | 5 | | | ns |
| tCHSL | CS# Not Active Hold Time | 5 | | | ns |
| tSHSL | CS# High Time (read/write) | 20 | | | ns |
| tSHQZ | Output Disable Time | | | 8 | ns |
| tCLQV | Clock Low To Output Valid | | | 5.5 | ns |
| tCLQX | Output Hold Time | 1.2 | | | ns |
| tDVCH | Data In Setup Time | 3 | | | ns |
| tCHDX | Data In Hold Time | 2 | | | ns |
| tHLCH | Hold# Low Setup Time(relative to Clock) | 5 | | | ns |
| tHHCH | Hold# High Setup Time(relative to Clock) | 5 | | | ns |
| tCHHL | Hold# High Hold Time(relative to Clock) | 5 | | | ns |
| tCHHH | Hold# Low Hold Time(relative to Clock) | 5 | | | ns |
| tHLQZ | Hold# Low To High-Z Output | | | 6 | ns |
| tHHQX | Hold# High To Low-Z Output | | | 6 | ns |
| tWHSL | Write Protect Setup Time Before CS# Low | 20 | | | ns |
| tSHWL | Write Protect Hold Time After CS# High | 100 | | | ns |
| tDP | CS# High To Deep Power-Down Mode | | | 3 | μs |
| tRES1 | CS# High To Standby Mode Without Electronic Signa- ture Read | | | 3 | μs |
| tRES2 | CS# High To Standby Mode With Electronic Signature Read | | | 3 | μs |
| tRST | CS# High To Next Command After Reset | | | 6 | μs |
| tSUS | CS# High To Next Command After Suspend | | | 20 | μs |
| tRS | Latency Between Resume And Next Suspend | 120 | | | μs |
| tWRSR | Write Status Register Cycle Time | | 0.8 | 10 | ms |
| tPP | Page Programming Time | | 0.35 | 1 | ms |
| tBP | Byte Programming Time (First Byte) | | 25 | 50 | μs |
| tBP | Byte Programming Time (After First Byte) | | 2.5 | 5 | μs |
| tSE | Sector Erase Time | | 40 | 700 | ms |



| tBE1 | Block Erase Time(32K Bytes) | 0.12 | 1.6 | S |
|------|-----------------------------|------|-----|---|
| tBE2 | Block Erase Time(64K Bytes) | 0.15 | 3.5 | S |
| tCE | Chip Erase Time | 2.5 | 5 | S |

Note:

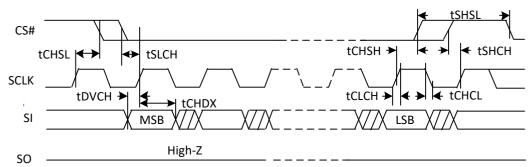
1. Clock high or Clock low must be more than or equal to 45%PC. PC=1/fC(MAX).

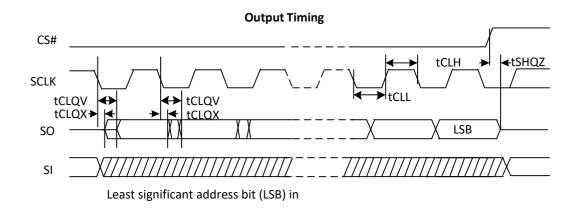
2. Typical values given for TA=25°C, VCC=1.8V. Value guaranteed by design and/or characterization, not 100% tested in production.

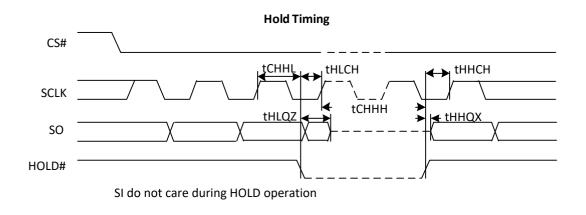
3. In order to ensure that the clock frequency can work up to the maximum datasheet value under continuous read mode, The High Speed Mode command (A3H) must be executed prior to Dual or Quad I/O commands, such as Dual I/O Fast Read (BBH), Quad I/O Fast Read (EBH), Quad I/O Word Fast Read (E7H), DTR Fast Read Dual I/O (BDH) and DTR Fast Read Quad I/O (EDH) commands.











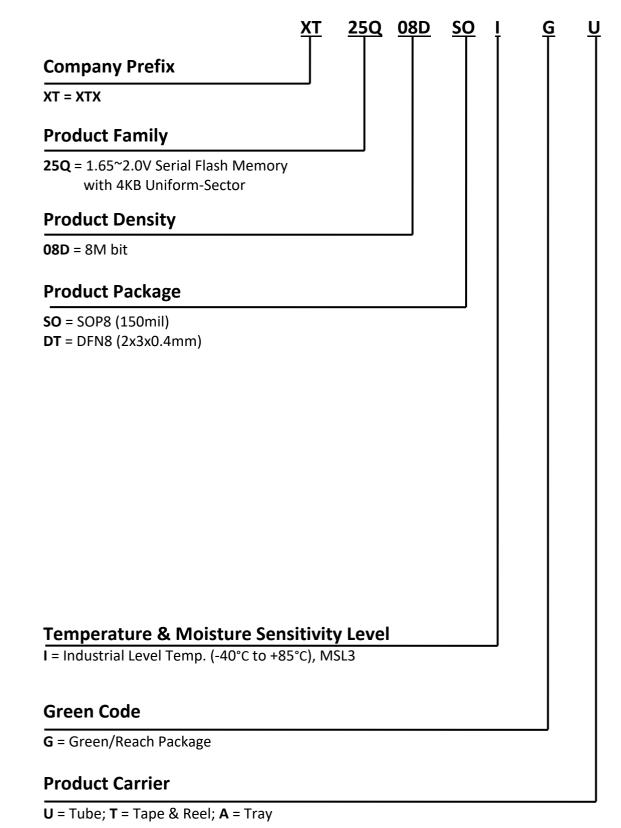






7. ORDERING INFORMATION

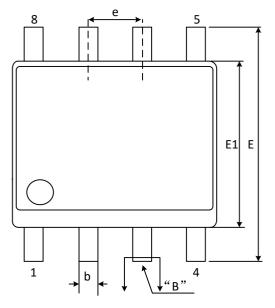
The ordering part number is formed by a valid combination of the following

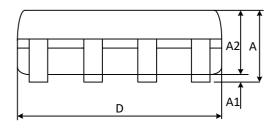


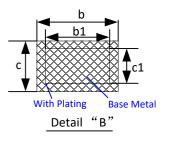


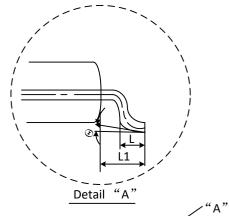
8. PACKAGE INFORMATION

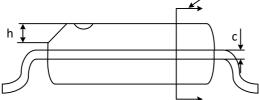
8.1. Package SOP8 150MIL







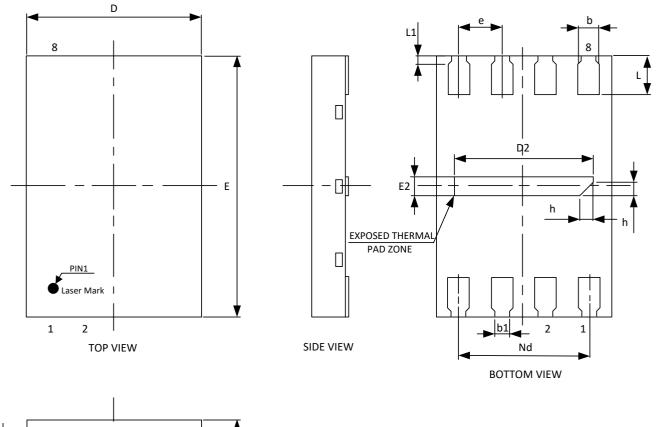


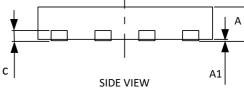


| SYMBOL | | MILLIMETEI | २ | |
|----------|---------|------------|------|--|
| STIVIBOL | MIN | NOM | MAX | |
| Α | — | _ | 1.75 | |
| A1 | 0.10 | — | 0.25 | |
| A2 | 1.30 | 1.40 | 1.50 | |
| b | 0.39 | — | 0.47 | |
| b1 | 0.38 | 0.41 | 0.44 | |
| С | 0.20 | — | 0.24 | |
| c1 | 0.19 | 0.20 | 0.21 | |
| D | 4.80 | 4.90 | 5.00 | |
| E1 | 3.80 | 3.90 | 4.00 | |
| е | | 1.27BSC | - | |
| E | 5.80 | 6.00 | 6.20 | |
| h | 0.25 | _ | 0.50 | |
| L | 0.50 | _ | 0.80 | |
| L1 | 1.05REF | | | |
| θ | 0° | _ | 8° | |



8.2. Package DFN8 (2x3x0.4) mm





| CYMPOL | | MILLIMETER | | | |
|--------|----------------|------------|------|--|--|
| SYMBOL | MIN | NOM | MAX | | |
| А | 0.35 | — | 0.40 | | |
| A1 | 0 | 0.02 | 0.05 | | |
| b | 0.20 | 0.25 | 0.30 | | |
| b1 | | 0.18REF | | | |
| с | 0.127REF | | | | |
| D | 1.90 | 2.00 | 2.10 | | |
| D2 | 1.50 | 1.60 | 1.70 | | |
| е | | 0.50BSC | | | |
| Nd | | 1.50BSC | | | |
| E | 2.90 | 3.00 | 3.10 | | |
| E2 | 0.10 | 0.20 | 0.30 | | |
| L | 0.40 | 0.45 | 0.50 | | |
| L1 | 0.05 0.10 0.15 | | | | |
| h | 0.10 | 0.15 | 0.20 | | |



9. REVISION HISTORY

| Revision | Description | Date |
|----------|--|--------------|
| 1.0 | Initial Version | Nov 30, 2020 |
| 1.1 | Operating Voltage range 1.65~2.1V 1.65~2.0V | Mar 23, 2021 |
| 1.2 | Update POD of SOP8 150mil, DFN8 2x3x0.4mm | Mar 29, 2021 |
| 1.3 | Update SFDP | Apr 23, 2021 |
| 1.4 | Add note about read frequency of EBH and BBH under Continuous Read Mode Add High Speed Mode(A3H) command Correct the value of Applied Input/Output Voltage and VCC in "Absolute Maxi- mum Ratings" section Add "Absolute Maximum Ratings Diagram" in "6.5.Capacitance Measurement Condition" section Correct wrong address range in Memory Description Adjust VOL from "1.6mA, 0.4V" to "100μA, 0.2V" Update the "Read Unique ID (RUID) Sequence" Added tCSL, tCSH, Setup Time, Hold Time values in The Reset Signaling Protocol (JEDEC 252) section | Sep 30, 2022 |